

## CORRECTIONS TO SOLUTIONS MANUAL

In the new edition, some chapter problems have been reordered and equations and figure references have changed. The solutions manual is based on the preview edition and therefore must be corrected to apply to the new edition. Below is a list reflecting those changes.

The “NEW” column contains the problem numbers in the new edition. If that problem was originally under another number in the preview edition, that number will be listed in the “PREVIEW” column on the same line. In addition, if a reference used in that problem has changed, that change will be noted under the problem number in quotes. Chapters and problems not listed are unchanged.

For example:

NEW	PREVIEW
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4.18	4.5
“Fig. 4.38”	“Fig. 4.35”
“Fig. 4.39”	“Fig. 4.36”

The above means that problem 4.18 in the new edition was problem 4.5 in the preview edition. To find its solution, look up problem 4.5 in the solutions manual. Also, the problem 4.5 solution referred to “Fig. 4.35” and “Fig. 4.36” and should now be “Fig. 4.38” and “Fig. 4.39,” respectively.

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## CHAPTER 3

NEW	PREVIEW
----	-----
3.1	3.8
3.2	3.9
3.3	3.11
3.4	3.12
3.5	3.13
3.6	3.14
3.7	3.15
“From 3.6”	“From 3.14”
3.8	3.16
3.9	3.17
3.10	3.18
3.11	3.19
3.12	3.20
3.13	3.21
3.14	3.22
3.15	3.1

3.16	3.2
3.17	3.2'
3.18	3.3
3.19	3.4
3.20	3.5
3.21	3.6
3.22	3.7
3.23	3.10
3.24	3.23
3.25	3.24
3.26	3.25
3.27	3.26
3.28	3.27
3.29	3.28

## CHAPTER 4

NEW	PREVIEW
-----	-----
4.1	4.12
4.2	4.13
4.3	4.14
4.4	4.15
4.5	4.16
4.6	4.17
4.7	4.18
“p. 4.6”	“p. 4.17”
4.8	4.19
4.9	4.20
4.10	4.21
4.11	4.22
4.12	4.23
4.13	4.24
“p. 4.9”	“p. 4.20”
4.14	4.1
“(4.52)”	“(4.51)”
“(4.53)”	“(4.52)”
4.15	4.2
4.16	4.3
4.17	4.4
4.18	4.5
“Fig. 4.38”	“Fig. 4.35”
“Fig. 4.39”	“Fig. 4.36”
4.19	4.6
“Fig 4.39(c)”	“Fig 4.36(c)”

4.20	4.7
4.21	4.8
4.22	4.9
4.23	4.10
4.24	4.11
4.25	4.25
4.26	4.26
“p. 4.9”	“p. 4.20”

## CHAPTER 5

NEW	PREVIEW
-----	-----
5.1	5.16
5.2	5.17
5.3	5.18
5.4	5.19
5.5	5.20
5.6	5.21
5.7	5.22
5.8	5.23
5.9	5.1
5.10	5.2
5.11	5.3
5.12	5.4
5.13	5.5
5.14	5.6
5.15	5.7
5.16	5.8
5.17	5.9
5.18	5.10
“Similar to 5.18(a)”	“Similar to 5.10(a)”
5.19	5.11
5.20	5.12
5.21	5.13
5.22	5.14
5.23	5.15

## CHAPTER 6

NEW	PREVIEW
-----	-----
6.1	6.7
6.2	6.8

6.3	6.9
“from eq(6.23)”	“from eq(6.20)”
6.4	6.10
6.5	6.11
“eq (6.52)”	“eq (6.49)”
6.6	6.1
6.7	6.2
6.8	6.3
6.9	6.4
6.10	6.5
6.11	6.6
6.13	6.13
“eq (6.56)”	“eq (6.53)”
“problem 3”	“problem 9”
6.16	6.16
“to (6.23) & (6.80)”	“to (6.20) & (6.76)”
6.17	6.17
“equation (6.23)”	“equation (6.20)”

## CHAPTER 7

NEW	PREVIEW
-----	-----
7.2	7.2
“eqn. (7.59)”	“eqn. (7.57)”
7.17	7.17
“eqn. (7.59)”	“eqn. (7.57)”
7.19	7.19
“eqns 7.66 and 7.67”	“eqns 7.60 and 7.61”
7.21	7.21
“eqn. 7.66”	“eqn. 7.60”
7.22	7.22
“eqns 7.70 and 7.71”	“eqns. 7.64 and 7.65”
7.23	7.23
“eqn. 7.71”	“eqn. 7.65”
7.24	7.24
“eqn 7.79”	“eqn 7.73”

## CHAPTER 8

NEW	PREVIEW
-----	-----
8.1	8.5
8.2	8.6



8.3	8.7
8.4	8.8
8.5	8.9
8.6	8.10
8.7	8.11
8.8	8.1
8.9	8.2
8.10	8.3
8.11	8.4
8.13	8.13
“problem 8.5”	“problem 8.9”

## CHAPTER 13

NEW	PREVIEW
-----	-----
3.17	3.17
“Eq. (3.123)”	“Eq. (3.119)”

CHAPTER 14 - New Chapter, “Oscillators”

CHAPTER 15 - New Chapter, “Phase-Locked Loops”

CHAPTER 16 - Was Chapter 14 in Preview Ed.

Change all chapter references in solutions manual from 14 to 16.

CHAPTER 17 - Was Chapter 15 in Preview Ed.

Change all chapter references in solutions manual from 15 to 17.

CHAPTER 18 - Was Chapter 16 in Preview Ed.

NEW	PREVIEW
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18.3	16.3
“Fig. 18.12(c)”	“Fig. 16.13(c)”
18.8	16.8
“Fig. 18.33(a,b,c,d)”	“Fig. 16.34(a,b,c,d)”

Also, change all chapter references from 16 to 18.

14.1 Open-Loop Transfer Function:

$$H(s) = \frac{-(g_m R_D)^2}{(1 + \frac{s}{\omega_0})^2}, \quad \omega_0 = \frac{1}{R_D C_L}$$

The gain drops to unity at  $\frac{g_m R_D}{(1 + \frac{\omega_u^2}{\omega_0^2})^{1/2}} = 1$ , which for  $g_m R_D \gg 1$ , yields,  $\omega_u \gg \omega_0$  and  $\omega_u \approx \omega_0 \cdot g_m R_D = \frac{g_m}{C_L}$ . The phase changes from  $-180^\circ$  at  $\omega \approx 0$  to  $-2 \tan^{-1} \frac{\omega_u}{\omega_0} - 180^\circ$  at  $\omega_u$ ; i.e., the phase change at  $\omega_u$  is  $-2 \tan^{-1}(g_m R_D)$  and the phase margin is equal to  $180^\circ - 2 \tan^{-1}(g_m R_D)$ .

14.2 (a)  $g_m R_D \geq 2 \Rightarrow R_D \geq 400 \Omega$ .

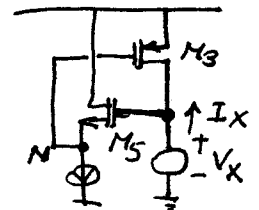
(b)  $\begin{cases} \omega_{osc} = \sqrt{3} \omega_0 = \sqrt{3}/(R_D C_L) \\ \text{Total Gain} = (g_m R_D)^3 = 16 \Rightarrow R_D = 504 \Omega \end{cases} \Rightarrow C_L = 0.547 \text{ pF}$

14.3 Each stage must provide a small-signal gain of 2. That is,  $g_{m1} R_1 = 2$ . With small swings, each transistor carries half of the tail current. For square-law devices, therefore, we have

$$g_{m1} R_1 = 2 = \sqrt{\mu_n C_{ox} \frac{W}{L} I_{SS}} R_1 = 2 \Rightarrow I_{SS} \geq \frac{4}{\mu_n C_{ox} \frac{W}{L} R_1^2}$$

14.4 Neglecting body effect of  $M_5$ , we have

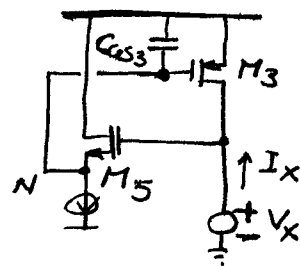
$V_N \approx V_X$ . Thus, the gate and drain of  $M_3$  experience equal voltage variations. That is,  $M_3$  operates as a diode-connected device, providing an impedance of  $1/g_{m3}$ .



$$14.5 \quad \frac{V_N}{V_X} = \frac{\frac{1}{C_{GS3} s}}{\frac{1}{C_{GS3} s} + \frac{1}{g_{m5}}} \quad (r = \lambda = 0)$$

$$= \frac{g_{m5}}{g_{m5} + C_{GS3} s} \Rightarrow \frac{I_X}{V_X} = \frac{g_{m3} g_{m5}}{g_{m5} + C_{GS3} s}$$

$$\Rightarrow \frac{V_X}{I_X} = \frac{1}{g_{m3}} + \frac{C_{GS3}}{g_{m3} g_{m5}} s \Rightarrow \text{The impedance is always inductive.}$$



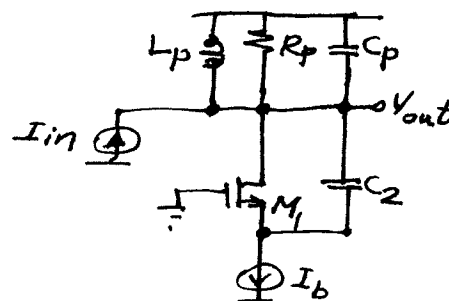
$$14.6 \quad \text{To avoid latchup, } g_m R_S < 1 \Rightarrow R_S < \frac{1}{g_m}.$$

14.7 The drain currents saturate near  $I_{SS}$  and 0 for a short while, creating a "suarish" waveform. The output voltages are the result of injecting the currents into the tanks. Since the tanks provide suppression at higher harmonics,  $V_X$  and  $V_Y$  are filtered versions of  $I_{D1}$  and  $I_{D2}$ .

14.8 For the circuit to oscillate, the loop gain must exceed unity:  $g_m R_P > 1 \Rightarrow g_m > \frac{1}{R_P}$ . For square-law devices,  $\sqrt{\mu_n C_{ox} \frac{W}{L} I_{SS}} > \frac{1}{R_P}$ . Thus,  $I_{SS} > \frac{1}{\mu_n C_{ox} \frac{W}{L} R_P^2}$ . For  $M_1$  and  $M_2$  not to enter the triode region, the maximum value of  $V_X$  and the minimum value of  $V_Y$  must differ by no more than  $V_{TH}$ . That is, the peak-to-peak swing at  $X$  or  $Y$  must be less than  $V_{TH}$ . Since the peak-to-peak swing is  $\approx I_{SS} R_P$ , we must have  $I_{SS} R_P < V_{TH}$ .

14.9 Since the total current flowing thru  $M_1$  and  $C_2$  is equal to  $I_b$ , a constant value.

$$\text{Thus, } \frac{V_{out}}{I_{in}} = (L_P s) \parallel R_P \parallel \frac{1}{C_P s},$$



14.10 Replace  $R_p$  with  $R_p \parallel \frac{1}{C_p s} = \frac{R_p}{R_p C_p s + 1}$  in Eq. (14.40). The

denominator then reduces to:

$$R_p C_1 C_2 L_p S^3 + (C_1 + C_2) L_p R_p C_p S^3 + (C_1 + C_2) L_p S^2 + [g_m L_p R_p C_p S + g_m L_p + R_p (C_1 + C_2)] S + g_m R_p$$

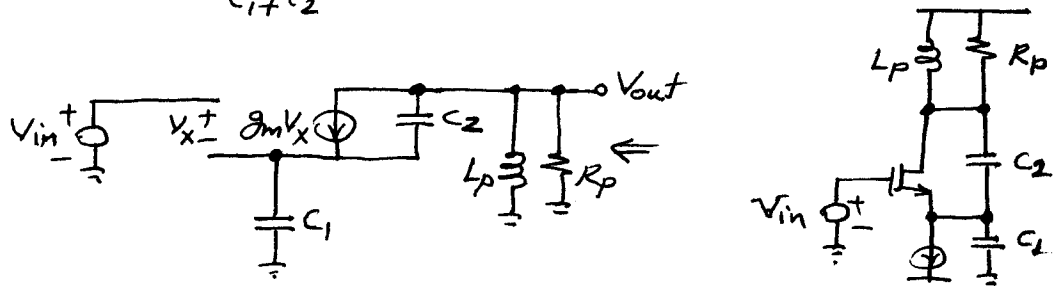
Grouping the imaginary terms and equating their sum to zero, we have

$$-R_p L_p \omega^3 [C_1 C_2 + (C_1 + C_2) C_p] + [g_m L_p + R_p (C_1 + C_2)] \omega = 0$$

Assuming  $g_m L_p \ll R_p (C_1 + C_2)$ , we obtain

$$\omega^2 = \frac{1}{L_p \left( \frac{C_1 C_2}{C_1 + C_2} + C_p \right)}$$

14.11



The current thru  $R_p \parallel (L_p s)$  is equal to  $V_{out} \left( \frac{1}{R_p} + \frac{1}{L_p s} \right)$ . The negative of this current flows thru  $C_1$ , generating a voltage  $-V_{out} \left( \frac{1}{R_p} + \frac{1}{L_p s} \right) \frac{1}{C_1 s}$  across it. Thus,  $V_x = V_{in} + V_{out} \left( \frac{1}{R_p} + \frac{1}{L_p s} \right) \frac{1}{C_1 s}$ . Also, the current thru  $C_2$  is equal to  $\left[ V_{out} + V_{out} \left( \frac{1}{R_p} + \frac{1}{L_p s} \right) \frac{1}{C_1 s} \right] C_2 s$ .

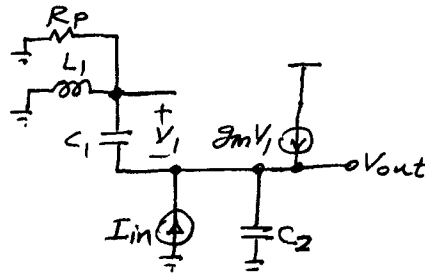
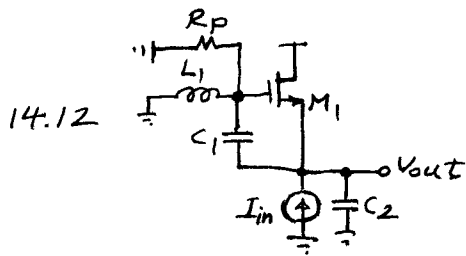
Adding  $g_m V_x$  and the current thru  $C_2$  and equating the result to  $-V_{out} \left( \frac{1}{R_p} + \frac{1}{L_p s} \right)$ , we have

$$\left[ V_{in} + V_{out} \left( \frac{1}{R_p} + \frac{1}{L_p s} \right) \frac{1}{C_1 s} \right] g_m + \left[ V_{out} + V_{out} \left( \frac{1}{R_p} + \frac{1}{L_p s} \right) \frac{1}{C_1 s} \right] C_2 s = -V_{out} \left( \frac{1}{R_p} + \frac{1}{L_p s} \right)$$

It follows that

$$\frac{V_{out}}{V_{in}} = \frac{-g_m L_p R_p C_1 S^2}{R_p L_p C_2 C_1 S^3 + L_p (C_1 + C_2) S^2 + [g_m L_p + R_p (C_1 + C_2)] S + g_m R_p}$$

Note that the denominator is the same as in Eq. (14.40).



$$V_1 = -(I_{in} - V_{out} C_2 s + g_m V_1) / C_1 s \Rightarrow V_1 (1 + g_m / C_1 s) = \frac{-I_{in} + V_{out} C_2 s}{C_1 s}$$

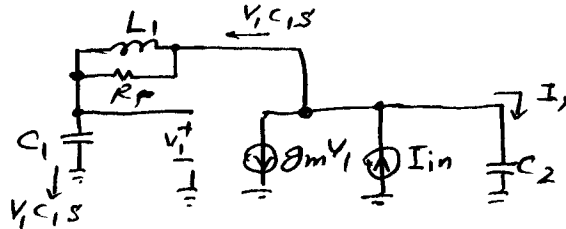
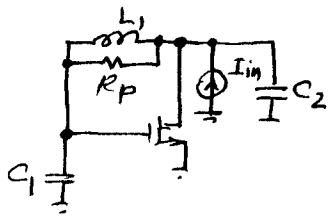
$$\Rightarrow V_1 = \frac{-I_{in} + V_{out} C_2 s}{g_m + C_1 s}$$

writing a KVL, we have  $-V_1 C_1 s \frac{R_p L_1 s}{R_p + L_1 s} = V_1 + V_{out}$ .

It follows that

$$V_{out} = - \frac{I_{in} + V_{out} C_2 s}{g_m + C_1 s} \left[ 1 + \frac{C_1 s R_p L_1 s}{R_p + L_1 s} \right]$$

Simplifying and calculating the denominator of  $V_{out}/I_{in}$ , we have  $R_p L_1 C_1 C_2 s^3 + L_1 (C_1 + C_2) s^2 + [R_p (C_1 + C_2) + g_m L_1] s + g_m R_p$ , which is the same as Eq. (14.40). Thus, the oscillation conditions are the same as those of Colpitts oscillator.



We can consider  $V_1$  as the output because for oscillation to begin the gain from  $I_{in}$  to  $V_1$  must be infinite as well. First, assume  $R_p \rightarrow \infty$ :

$$I_x = +V_1 C_1 s (L_1 s + \frac{1}{C_1 s}) C_2 s = -g_m V_1 + I_{in} - V_1 C_1 s$$

$$\Rightarrow V_1 [C_1 C_2 s^2 (L_1 s + \frac{1}{C_1 s}) + g_m + C_1 s] = I_{in}$$

Now, include  $R_p$ :  $V_1 \left[ C_1 C_2 s^2 \left( \frac{R_p L_1 s}{R_p + L_1 s} + \frac{1}{C_1 s} \right) + g_m + C_1 s \right] = I_{in}$

$$\Rightarrow V_1 \left[ \frac{C_1 C_2 s^2 (R_p C_1 L_1 s^2 + R_p + L_1 s) + (g_m + C_1 s) (C_1 s) (R_p + L_1 s)}{C_1 s (R_p + L_1 s)} \right] = I_{in}$$

$\Rightarrow$  denominator of  $V_1/I_{in}$  is  $(C_1 s \text{ is factored from numerator \& denominator.})$

$$R_p C_1 C_2 L_1 s^3 + R_p C_2 s + L_1 C_2 s^2 + g_m R_p + g_m L_1 s + C_1 R_p s + C_1 L_1 s^2$$

$$= R_p C_1 C_2 L_1 s^3 + L_1 (C_1 + C_2) s^2 + [R_p (C_1 + C_2) + g_m L_1] s + g_m R_p,$$

the same as that in Eq. (14.40).

14.13  $I_T = 1 \text{ mA}$ ,  $(\frac{W}{L})_{1,2} = 50/0.5$

(a) For a three-stage ring, the minimum gain per stage at low freqs must be 2. Thus,  $g_{m1,2} R_{1,2} = 2$  (when no current flows thru  $M_3$  and  $M_4$ ).  $\Rightarrow R_{1,2} = 2/g_{m1,2}$ . ( $g_{m1,2} = \sqrt{\mu_n C_{ox} (\frac{W}{L})_{1,2} I_T}$ .)

(b)  $g_{m3,4} R = 0.5$  with  $I_{D3,4} = 0.5 \text{ mA}$ .

$$g_{m3,4} = \sqrt{\mu_n C_{ox} (\frac{W}{L})_{3,4} I_T} = g_{m1,2} \sqrt{\frac{(W/L)_{3,4}}{(W/L)_{1,2}}} = \frac{2}{R}$$

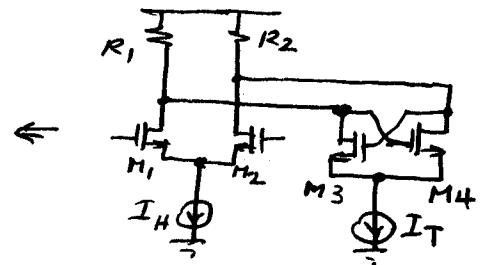
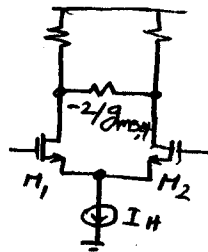
$$\Rightarrow \frac{2}{R} \sqrt{\frac{(W/L)_{3,4}}{(W/L)_{1,2}}} R = 0.5$$

$$\Rightarrow (W/L)_{3,4} = 0.25^2 (W/L)_{1,2}$$

(c) The voltage gain must be equal to 2 with a diff pair tail current of  $I_H$  while  $M_3$  and  $M_4$  carry all of  $I_T$ .

$$|A_v| = g_{m1,2} (R_{1,2} \parallel \frac{-1}{g_{m3,4}})$$

$$= g_{m1,2} \frac{R_{1,2}}{1 - g_{m3,4} R_{1,2}}$$



If  $g_{m3,4} R_{1,2} < 1$  (to avoid latch-up), then

$$g_{m1,2} R_{1,2} > 2(1 - g_{m3,4} R_{1,2})$$

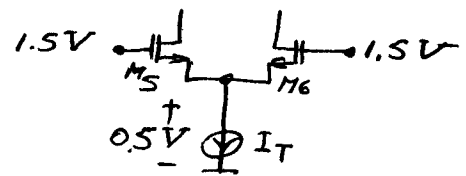
$$\Rightarrow \sqrt{2 \frac{I_H}{2} \mu_n C_{ox} (\frac{W}{L})_{1,2}} R_{1,2} > 2(1 - \sqrt{2 \frac{I_T}{2} \mu_n C_{ox} (\frac{W}{L})_{3,4}} R_{1,2})$$

Thus,  $I_H$  can be determined.

(d) Neglecting body effect for simplicity, we have

$$\frac{I_T}{2} = \frac{1}{2} \mu_n C_{ox} (\frac{W}{L})_{5,6} (V_{GSS,6} - V_{TH5,6})^2$$

$$\Rightarrow (\frac{W}{L})_{5,6} = \frac{I_T}{\mu_n C_{ox} (V_{GSS,6} - V_{TH5,6})^2} \text{ and } V_{GSS,6} + 0.5 \text{ V} = 1.5 \text{ V}.$$



14.14 If each inductor contributes a cap of  $C_1$ , then

$$f_{osc, min} = \frac{1}{2\pi\sqrt{L(C_0 + C_1)}} \quad , \quad f_{osc, max} = \frac{1}{2\pi\sqrt{L(0.62C_0 + C_1)}}$$

Thus, the tuning range is given by  $\frac{f_{osc, max}}{f_{osc, min}} = \sqrt{\frac{C_0 + C_1}{0.62C_0 + C_1}}$ ,

which is less than 27%. For example, if  $C_1 = 0.2C_0$ , then,

$$f_{osc, max} / f_{osc, min} \approx 1.21.$$

14.15 (a)  $L_p = 5 \text{ nH}$ ,  $C_x = 0.5 \text{ pF}$   $f_{osc} = 1 \text{ GHz} = \frac{1}{2\pi\sqrt{5 \text{ nH} \times (C_x + C_D)}}$

$$\Rightarrow C_D = 4.566 \text{ pF}.$$

(b)  $Q = \frac{L\omega}{R_p} = 4 \Rightarrow R_p = 125.7 \Omega \Rightarrow$

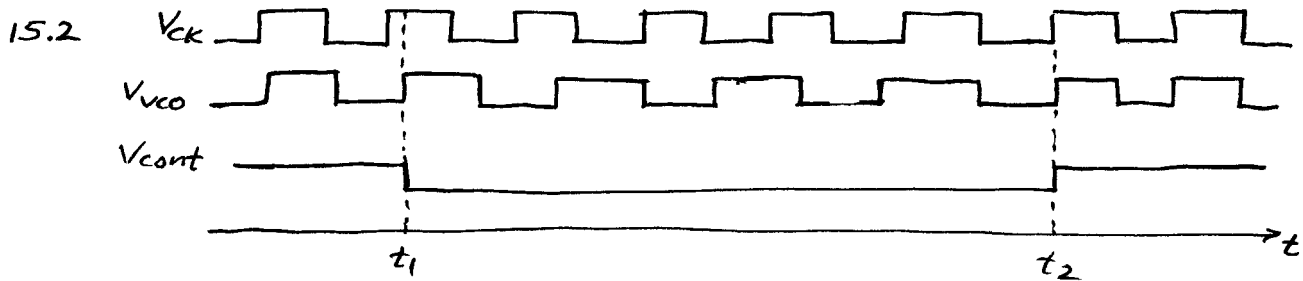
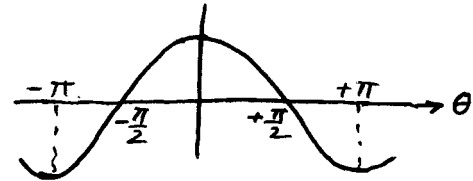
With a 1-mA tail current, the peak-to-peak swing on each side is approximately equal to 126 mV.

# Chapter 15 Phase-Locked Loops

15.1

15.1 With two signals  $V_1 \cos \omega t$  and  $V_2 \cos(\omega t + \theta)$ , the product is  $V_{out} = \frac{1}{2} V_1 V_2 [\cos(2\omega t + \theta) + \cos \theta]$ . If the high-freq. component is filtered out,  $V_{out} \propto \cos \theta$ .

The phase detector is linear only for a small neighborhood around  $\theta = \pm \frac{\pi}{2}$ .



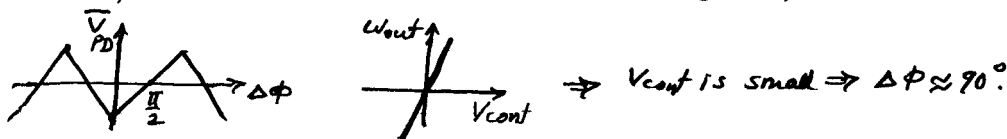
The difference between the two frequencies is integrated between  $t_1$  and  $t_2$  to accumulate a difference of  $\phi_0$ :

$$(f_H - f_L)(t_2 - t_1) = \frac{\phi_0}{2\pi}$$

$$\Rightarrow t_2 - t_1 = \frac{\phi_0}{2\pi(f_H - f_L)}$$

15.3 The VCO still requires a dc voltage that defines the frequency of operation. A high-pass filter would not provide the dc component.

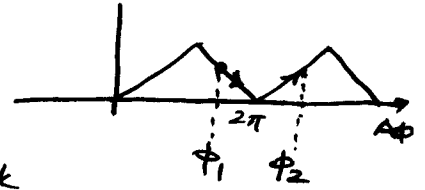
15.4 The loop must lock such that the phase difference is away from zero because the PD gain drops to zero at  $\Delta\phi = 0$ . With a large loop gain, the PD output settles around half of its full scale. This point can be better seen in a fully-differential implementation:



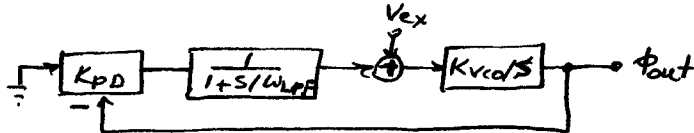


15.5 Suppose the loop begins with  $\Delta\phi = \phi_1$ .

If the feedback is positive, the loop accumulated so much phase to drive the PD toward  $\phi_2$ , where the feedback is negative and the loop can settle.



15.6 Note:  $\phi_{ex}$  should be changed to  $V_{ex}$ .



$$\left(-\phi_{out} \cdot K_{PD} \cdot \frac{1}{1 + \frac{s}{\omega_{LPF}}} + V_{ex}\right) \frac{K_{VCO}}{s} = \phi_{out}$$

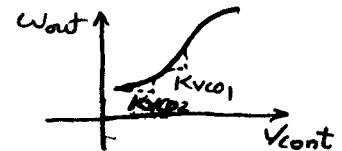
$$\Rightarrow \phi_{out} \left(1 + \frac{K_{PD} K_{VCO}}{s(1 + \frac{s}{\omega_{LPF}})}\right) = V_{ex} \frac{K_{VCO}}{s} \Rightarrow$$

$$\frac{\phi_{out}}{V_{ex}} = \frac{K_{VCO}}{s + \frac{K_{PD} K_{VCO}}{1 + \frac{s}{\omega_{LPF}}}} = \frac{K_{VCO}(1 + \frac{s}{\omega_{LPF}})}{\frac{s^2}{\omega_{LPF}^2} + s + K_{PD} K_{VCO}}$$

15.7  $\zeta = \frac{1}{2} \sqrt{\frac{\omega_{LPF}}{K_{PD} K_{VCO}}} \sqrt{\frac{K_{VCO1}}{K_{VCO2}}} = 1.5$

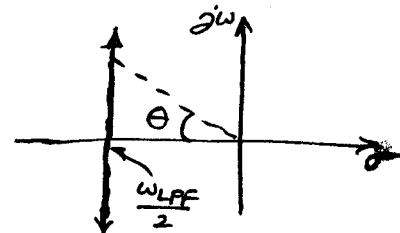
$$\Rightarrow \frac{K_{VCO1}}{K_{VCO2}} = 2.25$$

The slope can vary by a factor of 2.25.



15.8  $\tan \varphi = \frac{\text{Im}(\text{pole})}{-\text{Re}(\text{pole})} = \frac{\sqrt{1-\zeta^2}}{\zeta}$

This is indeed as if  $\zeta = \cos \varphi$  and  $\sqrt{1-\zeta^2} = \sin \varphi$ .



15.9  $K_{VCO} = 100 \text{ MHz/V}$ ,  $K_{PD} = 1 \text{ V/rad}$ ,  $\omega_{LPF} = 2\pi(1 \text{ MHz})$

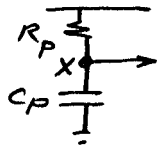
$$\Rightarrow \zeta = \frac{1}{2} \sqrt{\frac{1 \text{ MHz}}{(1 \text{ V/rad})(100 \text{ MHz/V})}} = 0.05 \quad \frac{\omega_n}{2\pi} = \sqrt{(1 \text{ MHz})(1 \text{ V/rad})(100 \text{ MHz/V})} = 10 \text{ MHz}$$

The loop is heavily underdamped.

$$\tau = 318 \text{ ns}$$

$$\text{Step response} \approx [1 - e^{-t/318 \text{ ns}} \sin(2\pi \times 10 \text{ MHz} \times t + \theta)] u(t), \theta \leq 90^\circ$$

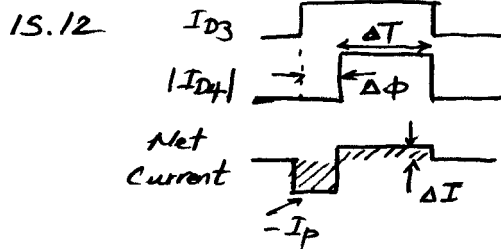
15.10



If the control voltage is sensed at node X, then  $R_P$  appears in series with the current sources in the charge pump, failing to provide a zero.

15.11 From (15.40),  $\frac{I_{out}}{\Delta\phi}(s) = \frac{I_P}{2\pi}$ . Since  $I_{out}$  is multiplied by the series combination of  $R_P$  and  $C_P$ :

$$\frac{V_{out}}{\Delta\phi}(s) = \frac{I_P}{2\pi} (R_P + \frac{1}{C_P s}).$$



$\Delta\phi$  must be such that the net current is zero. If the current mismatch equals  $\Delta I$  and the width of  $|I_{D4}|$  pulses is  $\Delta T$ , then

$$(\frac{\Delta\phi}{2\pi} \cdot T_P) I_P = \Delta T \cdot \Delta I, \text{ where } T_P \text{ is the period.}$$

$$\Rightarrow \Delta\phi = 2\pi \frac{\Delta T}{T_P} \cdot \frac{\Delta I}{I_P}$$

15.13  $\omega_{out} = \omega_0 + K_{VCO} V_{cont}$ ,  $V_{cont} = V_m \cos \omega_m t$ . The VCO output is

$$V_{out} = V_0 \cos \left[ \int \omega_{out} dt \right] = V_0 \cos \left[ \omega_0 t + K_{VCO} V_m \int \cos \omega_m t dt \right]$$

$$= V_0 \cos \omega_0 t \cos \left( K_{VCO} \frac{V_m}{\omega_m} \sin \omega_m t \right) - V_0 \sin \omega_0 t \sin \left( K_{VCO} \frac{V_m}{\omega_m} \sin \omega_m t \right).$$

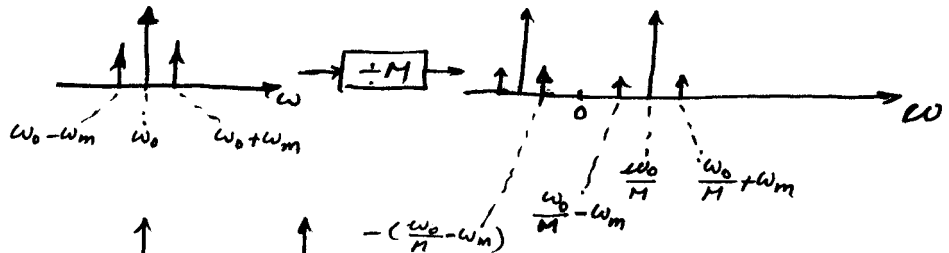
For small  $V_m$ ,  $V_{out}(t) \approx V_0 \cos \omega_0 t - \frac{K_{VCO} V_m V_0}{2 \omega_m} [\cos(\omega_0 - \omega_m)t - \cos(\omega_0 + \omega_m)t].$

The divider output is expressed as

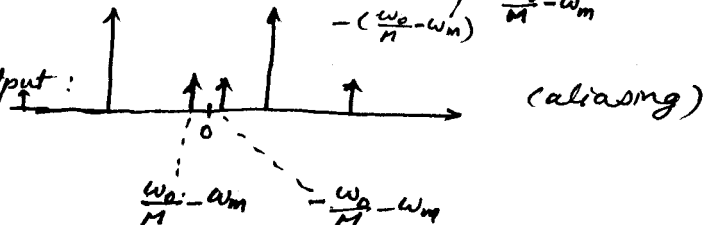
$$V_{out,M} = V_0 \cos \left[ \frac{\omega_0 t}{M} + \frac{K_{VCO} V_m}{M} \int \cos \omega_m t dt \right]$$

$$\approx V_0 \cos \frac{\omega_0}{M} t - \frac{K_{VCO} V_m V_0}{2 M \omega_m} \left[ \cos \left( \frac{\omega_0}{M} - \omega_m \right) t - \cos \left( \frac{\omega_0}{M} + \omega_m \right) t \right].$$

If  $\frac{\omega_0}{M} > \omega_m$ ,



If  $\frac{\omega_0}{M} > \omega_m$ , output:



$$15.14 \quad S_{1,2} = -\xi \omega_n \pm \omega_n \sqrt{\xi^2 - 1} \quad \begin{aligned} \xi &\propto \sqrt{I_p K_{vco}} \\ \omega_n &\propto \sqrt{I_p K_{vco}} \end{aligned}$$

As  $I_p K_{vco}$  starts from small values,  $S_{1,2}$  are complex:

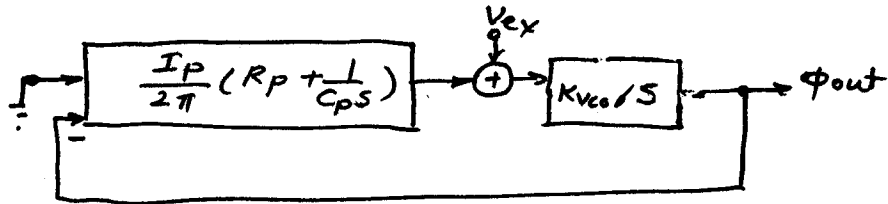
$$\operatorname{Re}\{S_{1,2}\} = -\xi \omega_n \quad \operatorname{Im}\{S_{1,2}\} = \pm \omega_n \sqrt{1 - \xi^2}.$$

Noting that  $\omega_n = \frac{2\xi}{R_p C_p}$ , we can write  $\omega_n^2 - \frac{2\xi \omega_n}{R_p C_p} = 0$

Adding  $(\frac{1}{R_p C_p})^2$  to both sides and subtracting and adding  $-\xi^2 \omega_n^2$ , we obtain  $(-\xi \omega_n + \frac{1}{R_p C_p})^2 + \omega_n^2(1 - \xi^2) = (\frac{1}{R_p C_p})^2$ , which is a circle centered at  $-\frac{1}{R_p C_p}$  with a radius equal to  $\frac{1}{R_p C_p}$ .

For  $\xi \geq 1$ , the poles become real and move away from each other:  $-\xi \omega_n + \omega_n \sqrt{\xi^2 - 1}$  and  $-\xi \omega_n - \omega_n \sqrt{\xi^2 - 1}$ . If  $\xi \rightarrow \infty$ , then  $-\xi \omega_n + \omega_n \sqrt{\xi^2 - 1} = \omega_n(-\xi + \sqrt{\xi^2 - 1}) = \omega_n \xi(-1 + \sqrt{1 - \frac{1}{\xi^2}}) \approx \omega_n \xi(-1 + (1 - \frac{1}{2\xi^2})) \approx \frac{-\omega_n}{2\xi} = \frac{-1}{R_p C_p}$ .

15.15 Note:  $\phi_{ex}$  should be changed to  $V_{ex}$ .



$$\begin{aligned} &\left[ -\phi_{out} \cdot \frac{I_p}{2\pi} \left( \frac{R_p C_p s + 1}{C_p s} \right) + V_{ex} \right] \frac{K_{vco}}{s} = \phi_{out} \\ \Rightarrow \phi_{out} \left[ 1 + \frac{I_p K_{vco} (R_p C_p s + 1)}{2\pi C_p s^2} \right] &= V_{ex} \frac{K_{vco}}{s} \Rightarrow \\ \frac{\phi_{out}}{V_{ex}} &= \frac{K_{vco} (2\pi C_p s^2)}{2\pi C_p s^2 + I_p K_{vco} R_p C_p s + 1} \end{aligned}$$

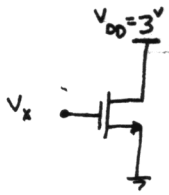
15.16 When the VCO frequency is far from the input frequency, the PFD operates as a frequency detector, comparing the VCO and input frequencies. Thus, the VCO transfer function must relate the output frequency to the control voltage:

$\Delta \omega_{out} = K_{VCO} \Delta V_{cont} \Rightarrow$  the order of the system falls by one (compared to when the VCO phase is of interest:  $K_{VCO}/s$ .)

# Chapter 2

2.1

2.1) a) NMOS :

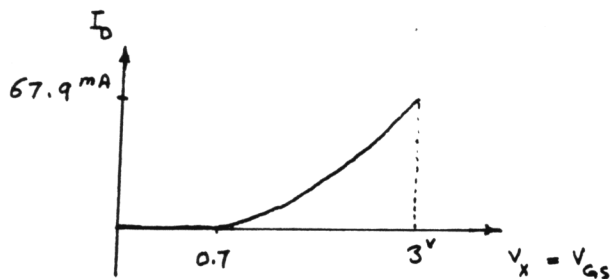


for  $V_x < V_{th} (= 0.7)$  device is off ,  $I_D \approx 0$

for  $V_x \geq 0.7$

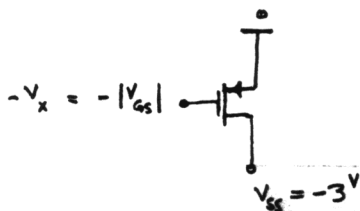
$$I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L_{eff}} (V_x - 0.7)^2 (1 + \lambda \cdot 3^V) \quad (L_{eff} = 0.5^{\mu} - 2L_0)$$

$$I_D = 12.8 \left( \frac{mA}{V^2} \right) \cdot (V_x - 0.7)^2$$



b) PMOS :

Solution is the same

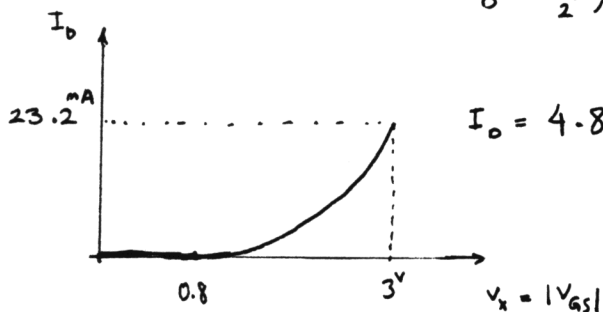


for  $|V_{GS}| < V_{th} (= 0.8)$   $I_D \approx 0$

for  $|V_{GS}| \geq 0.8$

$$I_D = \frac{1}{2} \mu_p C_{ox} \frac{W}{L_{eff}} (V_x - 0.8)^2 (1 + \lambda \cdot 3^V)$$

$$I_D = 4.8 \left( \frac{mA}{V^2} \right) \cdot (V_x - 0.8)^2$$



2.2) a) NMOS

$$g_m = \sqrt{2\mu_n C_{ox} \frac{W}{L} I_D} = 3.66 \frac{mA}{V} \quad (\text{Neglecting } L_D)$$

$$r_o = \frac{1}{\lambda I_D} = 20 \text{ k}\Omega$$

$$\text{Intrinsic gain} = g_m r_o = 733 \frac{V}{V}$$

b) PMOS

$$g_m = \sqrt{2\mu_p C_{ox} \frac{W}{L} I_D} = 1.96 \frac{mA}{V}$$

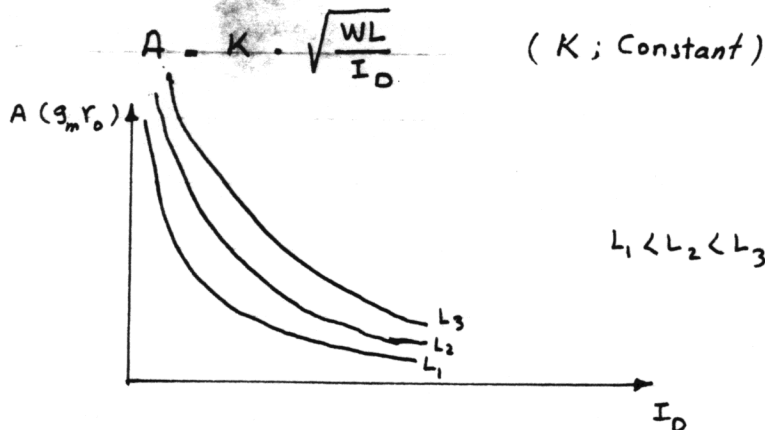
$$r_o = \frac{1}{\lambda I} = \frac{1}{0.2 \cdot 0.5 \text{ mA}} = 10 \text{ k}\Omega$$

$$g_m r_o = 19.6 \frac{V}{V}$$

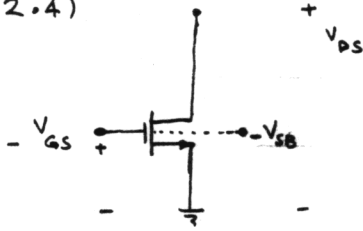
$$2.3) \quad g_m = \sqrt{2\mu C_{ox} \frac{W}{L} I_D} \quad r_o = \frac{1}{\lambda I_D}$$

$$\text{Assume } \lambda = \frac{d}{L}$$

$$A = g_m r_o = \sqrt{2\mu C_{ox} \frac{W}{L} I_D} \cdot \frac{L}{\alpha I_D}$$



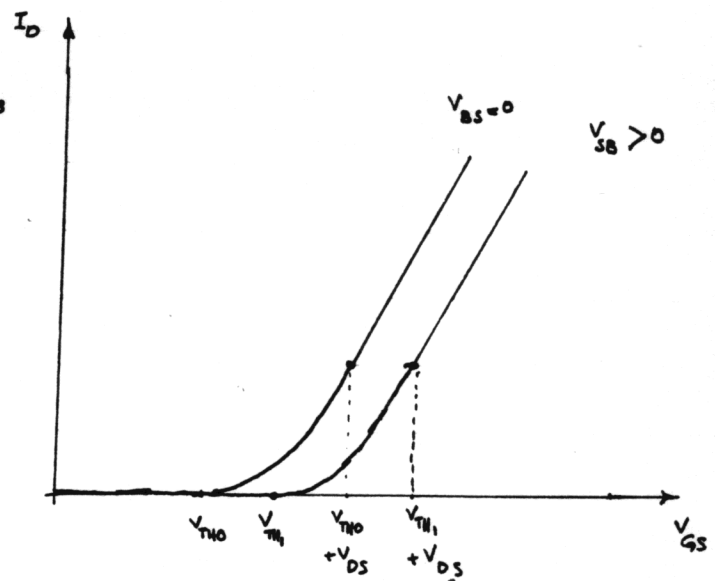
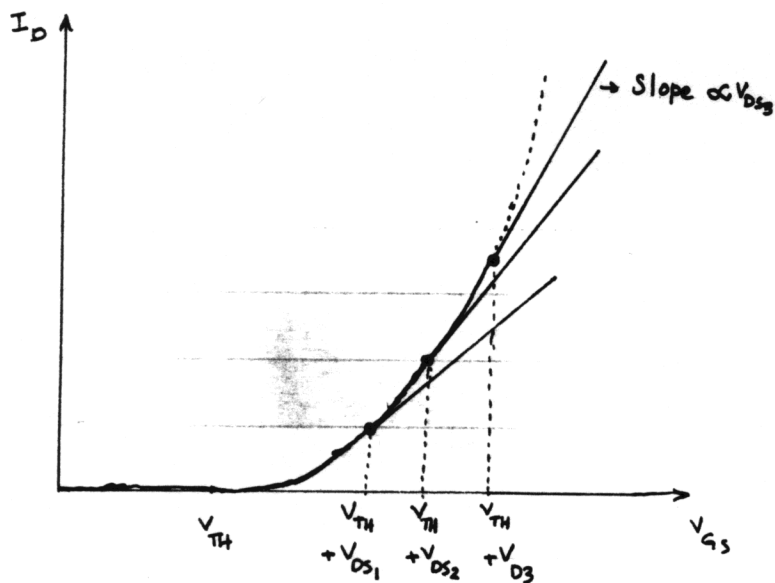
2.4)

 $I_D$  versus  $V_{GS}$  : (for NMOS)I) for  $V_{GS} < V_{TH}$  ,  $I_D \approx 0$ II) for  $V_{TH} < V_{GS} < V_{TH} + V_{DS} \Rightarrow$  Device is in the Saturation region

$$I_D \approx \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{GS} - V_{TH})^2$$

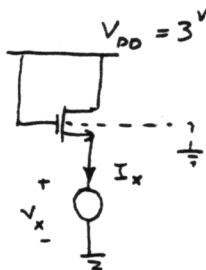
III) for  $V_{GS} > V_{TH} + V_{DS} \Rightarrow$  Device operates in the triode region

$$I_D \approx \mu_n C_{ox} \frac{W}{L} \left[ (V_{GS} - V_{TH}) V_{DS} - \frac{1}{2} V_{DS}^2 \right]$$



Changing  $V_{SB}$  just shifts the curve to the right for  $V_{SB} > 0$  or to the left for  $V_{SB} < 0$

2.5) a)



$$\lambda = 0.1, \quad \gamma = 0.45, \quad 2\phi_F = 0.9, \quad V_{TH0} = 0.7$$

$$V_{GS} = 3 - V_x, \quad V_{DS} = 3 - V_x, \quad V_{SB} = V_x$$

$$V_{TH} = V_{TH0} + \gamma (\sqrt{2\phi_F + V_{SB}} - \sqrt{2\phi_F})$$

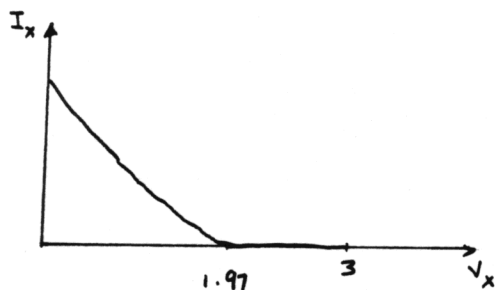
$$\text{So, } I_x = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (3 - V_x - 0.7 - 0.45(\sqrt{0.9 + V_x} - \sqrt{0.9}))^2 (1 + \lambda(3 - V_x))$$

The above equation is valid for

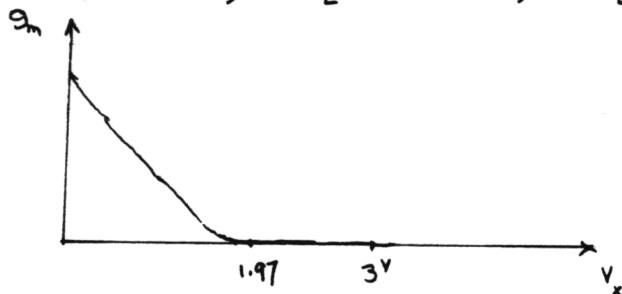
$$3 - V_x - 0.7 - 0.45(\sqrt{0.9 + V_x} - \sqrt{0.9}) > 0, \quad \text{i.e. } V_x < 1.97 \text{ V}$$

$$\text{So, } I_x = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (2.727 - V_x - 0.45\sqrt{0.9 + V_x})^2 (1.3 - 0.1 V_x)$$

$$\text{and } I_x = 0 \text{ for } 1.97 < V_x$$

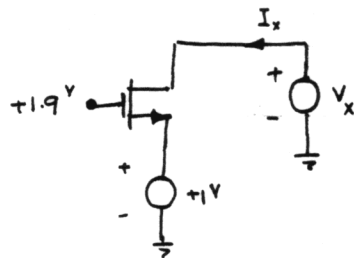


$$g_m = \sqrt{2 \mu_n C_{ox} \frac{W}{L} I_D} = \sqrt{2 \mu_n C_{ox} \frac{W}{L} I_x}$$





2.5) b,



$$\lambda = \gamma = 0 \quad V_{TH} = 0.7$$

for  $0 < V_x < 1$ , S and D exchange their roles.

$$V_{GS} = 1.9 - V_x \quad V_{DS} = 1 - V_x, \quad V_{SD} = 1.2 - V_x$$

$$I_x = -\frac{1}{2} \mu_n C_{ox} \frac{W}{L} \left[ (1.2 - V_x) \times 2 \times (1 - V_x) - (1 - V_x)^2 \right]$$

$$I_x = -\frac{1}{2} \mu_n C_{ox} \frac{W}{L} (1 - V_x) (1.4 - V_x)$$

$$g_m = \mu_n C_{ox} \frac{W}{L} V_{DS} = \mu_n C_{ox} \frac{W}{L} (1 - V_x) \text{ (absolute value)}$$

The above equations are valid for  $V_x < 1$

Then the direction of current is reversed.

$$V_{GS} = 1.9 - 1 = 0.9 \quad V_{DS} = V_x - 1, \quad V_{SD} = 0.9 - 0.7 = 0.2$$

for  $V_x < 1.2$ , device operates in the triode region.

$$I_x = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \left[ 2 \times 0.2 \times (V_x - 1) - (V_x - 1)^2 \right]$$

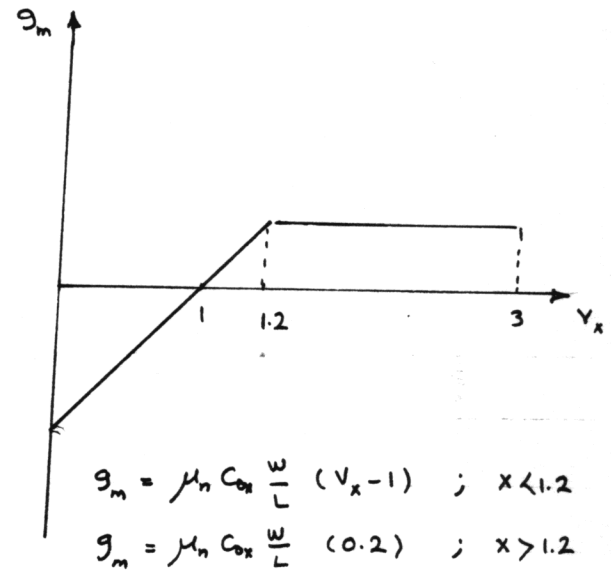
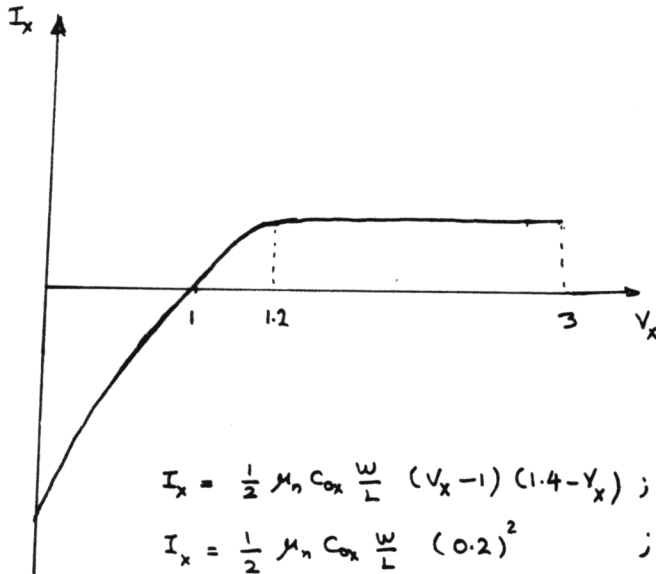
$$g_m = \mu_n C_{ox} \frac{W}{L} (V_x - 1)$$

for  $V_x > 1.2$ , Device goes into saturation region

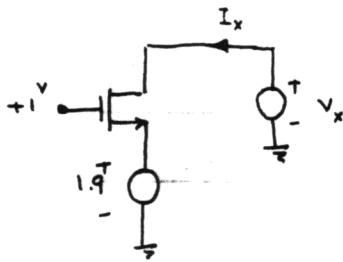
2.5) b Cont

$$\text{So, } I_x = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (0.2)^2 ,$$

$$g_m = \mu_n C_{ox} \frac{W}{L} (0.2)$$



2.5) c



$$\lambda = \gamma = 0$$

$$V_{TH} = 0.7$$

S and D exchange their roles.

$$V_{GS} = 1 - V_x$$

$$V_{DS} = 1.9 - V_x$$

$$V_{OD} = V_{GS} - V_{TH} = 0.3 - V_x$$

Device is in saturation region, so,  $I_x = -\frac{1}{2} \mu_n C_{ox} \frac{W}{L} (0.3 - V_x)^2$

Device turns off when  $V_x = 0.3$  and never turns on again.

$$\text{So, } I_x = -\frac{1}{2} \mu_n C_{ox} \frac{W}{L} (0.3 - V_x)^2 ; x < 0.3$$

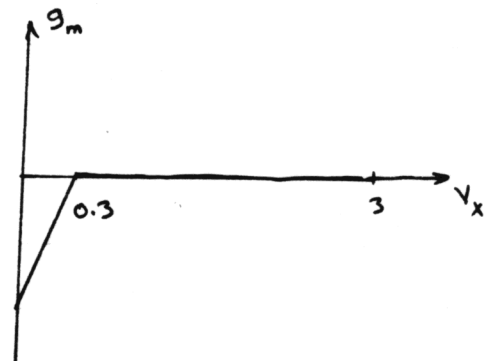
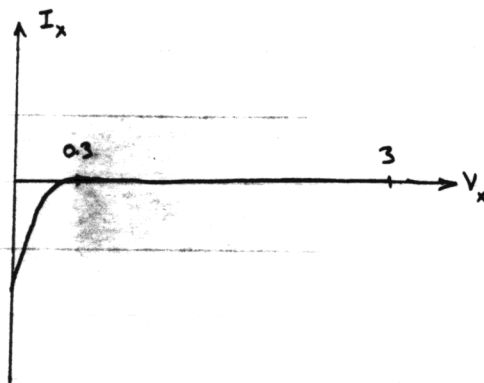
$$I_x = 0$$

; otherwise

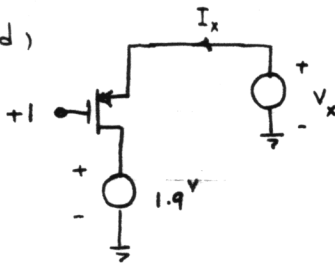
$$\text{Then } g_m = -\mu_n C_{ox} \frac{W}{L} (0.3 - V_x) ; x < 0.3$$

$$g_m = 0$$

; otherwise



2.5) d)



$$V_{TH} = -0.8$$

$$\gamma = 0$$

D and S exchange their roles.

$$V_{GS} = -0.9$$

$$V_{DS} = V_x - 1.9$$

for  $V_x < 1.8$  :

$$I_x = -\frac{1}{2} \mu_p C_{ox} \frac{W}{L} (0.1)^2$$

$$g_m = -\mu_p C_{ox} \frac{W}{L} (0.1)$$

Device remains in the saturation region until

$$V_x = 1.9 - 0.1 = 1.8, \text{ then device goes into the triode}$$

region.

for  $1.8 < V_x < 1.9$  :

$$I_x = -\mu_p C_{ox} \frac{W}{L} \left[ (-0.1)(V_x - 1.9) - \frac{1}{2} (V_x - 1.9)^2 \right]$$

$$g_m = +\mu_p C_{ox} \frac{W}{L} (V_x - 1.9)$$

for  $V_x > 1.9$  :

S and D exchange their roles again, when  $V_x = 1.9$

for  $V_x > 1.9$ , Device operates in the triode region.

$$V_{GS} = 1 - V_x, \quad V_{DS} = 1.9 - V_x$$

$$I_x = +\mu_p C_{ox} \frac{W}{L} \left[ (1.8 - V_x)(1.9 - V_x) - \frac{1}{2} (1.9 - V_x)^2 \right]$$

$$g_m = -\mu_p C_{ox} \frac{W}{L} (1.9 - V_x)$$

$$2.5)d \quad 50; \quad 0 < V_x < 1.8$$

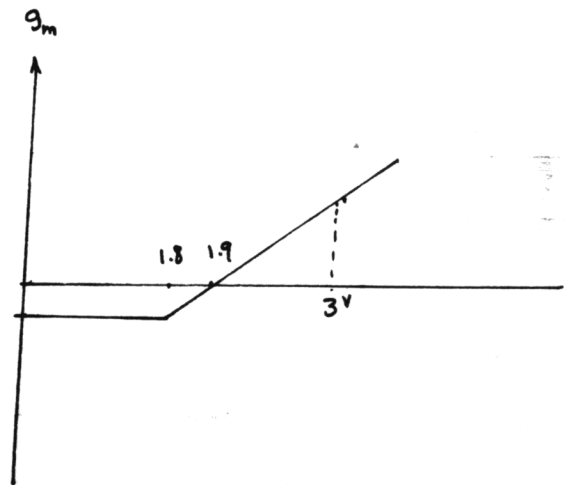
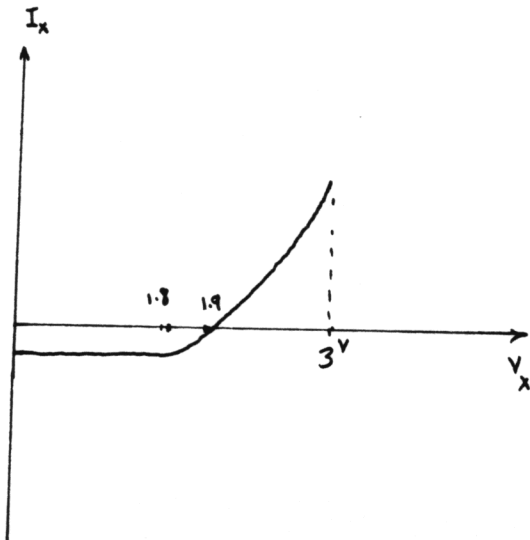
$$I_x = -\frac{1}{2} \mu_p C_{ox} \frac{W}{L} (0.1)^2$$

$$g_m = -\mu_p C_{ox} \frac{W}{L} (0.1)$$

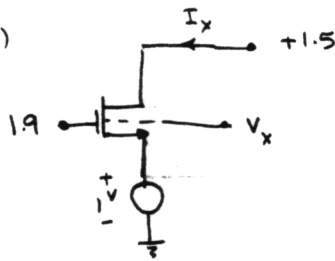
$$1.8 < V_x < 3$$

$$I_x = +\mu_p C_{ox} \frac{W}{L} \times \frac{1}{2} (V_x - 1.9)(V_x - 1.7)$$

$$g_m = \mu_p C_{ox} \frac{W}{L} (V_x - 1.9)$$



2.5) e)



$$V_{TH0} = 0.7 \quad \gamma = 0.45 \quad 2\phi_F = 0.9 \quad , \lambda = 0$$

$$V_{SB} = 1 - V_x$$

$$V_{TH} = 0.7 + 0.45 (\sqrt{0.9 + 1 - V_x} - \sqrt{0.9})$$

$$V_{GS} = 0.9$$

$$V_{DS} = 0.5$$

for  $V_x = 0$  ,  $V_{TH} = 0.893$  So device is in saturation region.

$$\text{So } I_x = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (0.2 - 0.45 (\sqrt{1.9 - V_x} - \sqrt{0.9}))^2$$

$$g_m = \mu_n C_{ox} \frac{W}{L} (0.2 - 0.45 (\sqrt{1.9 - V_x} - \sqrt{0.9}))$$

These equations are valid upto the edge of triode region, i.e.

$$0.2 - 0.45 (\sqrt{1.9 - V_x} - \sqrt{0.9}) = 0.5 \Rightarrow V_x = 1.82$$

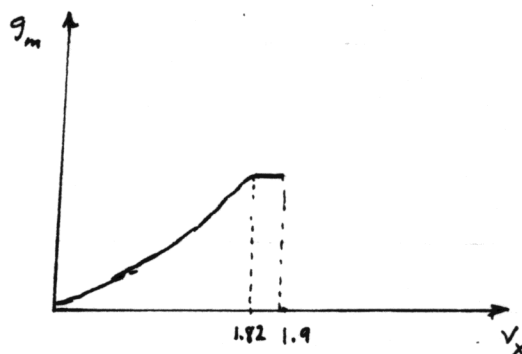
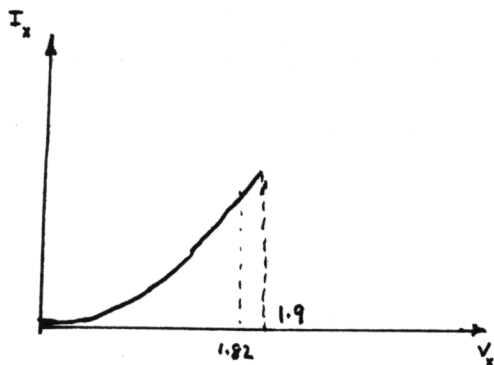
Above  $V_x = 1.82$  , device is in the triode region.

$$I_x = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} [2 \times 0.5 \times (0.2 - 0.45 (\sqrt{1.9 - V_x} - \sqrt{0.9})) - 0.5^2]$$

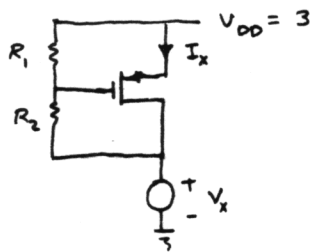
$$g_m = \mu_n C_{ox} \frac{W}{L} (0.5) \quad ; \text{ This problem has been considered}$$

only for  $0 < V_x < 1.9$  in which

Schichman-Hodges Eq. is valid for  $V_{TH}$ .



2.6) a)



$$\gamma = 0$$

$$V_{SG} = (V_{DD} - V_x) \frac{R_1}{R_1 + R_2}$$

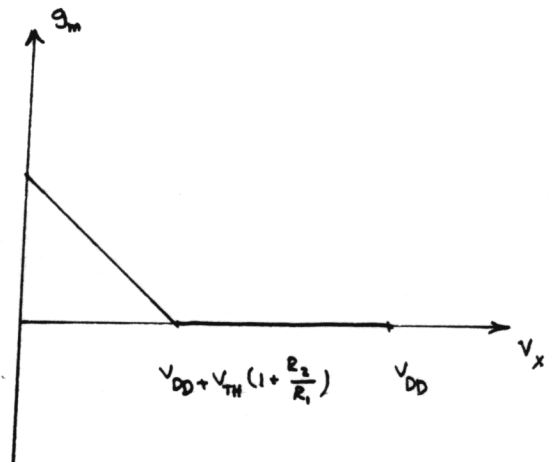
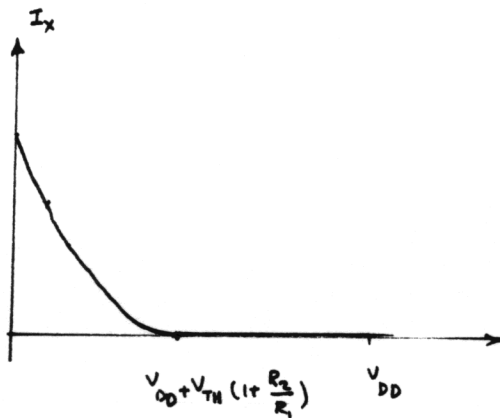
$$V_{SD} = V_{DD} - V_x$$

for  $V_{SG} > |V_{TH}|$  Device is in the Saturation region (Device is

off; otherwise)  $(V_{DD} - V_x) \frac{R_1}{R_1 + R_2} > -V_{TH}$

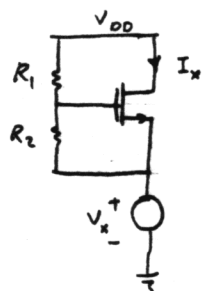
$$V_x < V_{DD} + V_{TH} \left(1 + \frac{R_2}{R_1}\right) \Rightarrow I_x = \frac{1}{2} \mu_p C_{ox} \frac{W}{L} \left[ (V_{DD} - V_x) \frac{R_1}{R_1 + R_2} + V_{TH} \right]^2$$

$$g_m = \mu_p C_{ox} \frac{W}{L} \left[ (V_{DD} - V_x) \frac{R_1}{R_1 + R_2} + V_{TH} \right]$$



If  $V_{DD} + V_{TH} \left(1 + \frac{R_2}{R_1}\right) < 0$  (e.g. for small value of  $R_1$ ), device never turns on!

2.6) b)



$$\gamma = 0$$

$$V_{GS} = (V_{DD} - V_x) \frac{R_2}{R_1 + R_2}$$

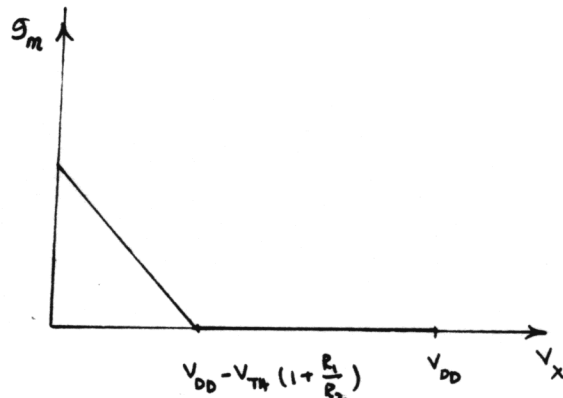
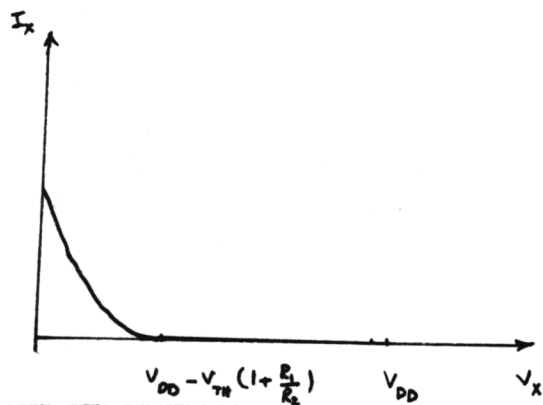
$$V_{DS} = V_{DD} - V_x$$

for  $V_{GS} > V_{TH}$ , Device is in the saturation region and

$$I_x = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \left[ (V_{DD} - V_x) \frac{R_2}{R_1 + R_2} - V_{TH} \right]^2$$

$$g_m = \mu_n C_{ox} \frac{W}{L} \left[ (V_{DD} - V_x) \frac{R_2}{R_1 + R_2} - V_{TH} \right]$$

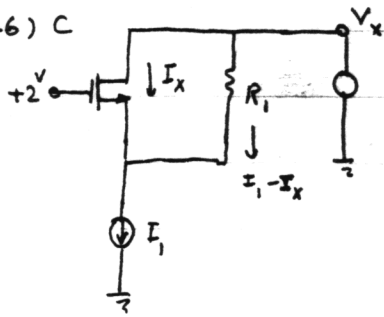
for  $V_x < V_{DD} - V_{TH} (1 + \frac{R_1}{R_2})$  (i.e.  $V_{GS} > V_{TH}$ )



If  $V_{DD} - V_{TH} (1 + \frac{R_1}{R_2}) < 0$  device doesn't turn on.



2.6) C



$I_x$  and  $I_R = I_1 - I_x$  have the same polarity

So,  $0 \leq I_x \leq I_1$

for  $0 < V_x < 2 - V_{TH}$  (1.3) Device is in the triode.

$$V_{GS} = 2 - V_x + R_1 (I_1 - I_x), \quad V_{DS} = R_1 (I_1 - I_x)$$

$$I_x = I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} [2(V_{GS} - V_{TH}) - V_{DS}] V_{DS}$$

$$\Rightarrow (*) I_x = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} [R_1 (I_1 - I_x) + 2(2 - V_{TH} - V_x)] [R_1 (I_1 - I_x)]$$

The above equation presents  $I_x - V_x$  characteristics in this region.

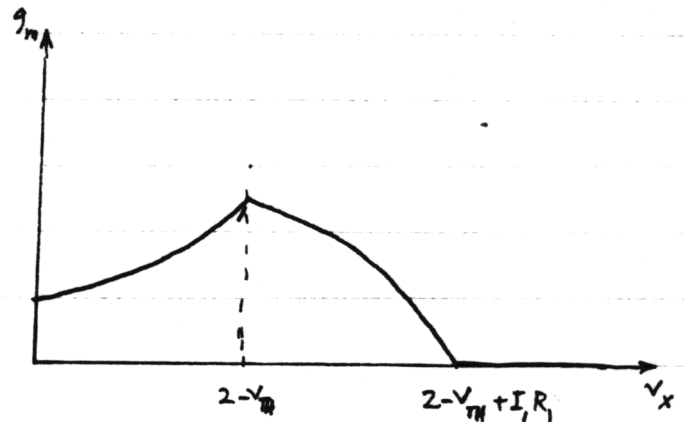
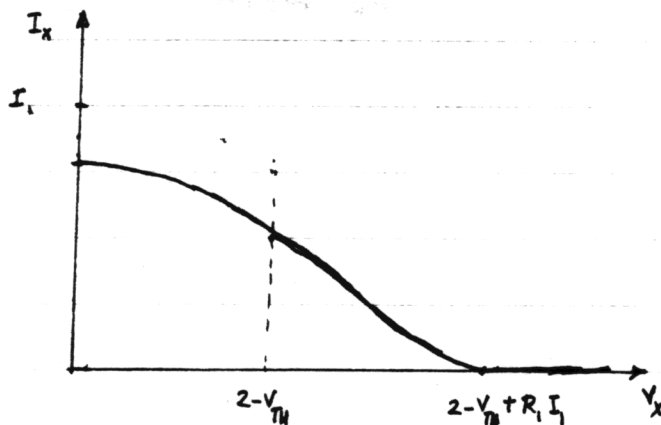
In this region  $g_m = \mu_n C_{ox} V_{DS} = \mu_n C_{ox} R_1 (I_1 - I_x)$

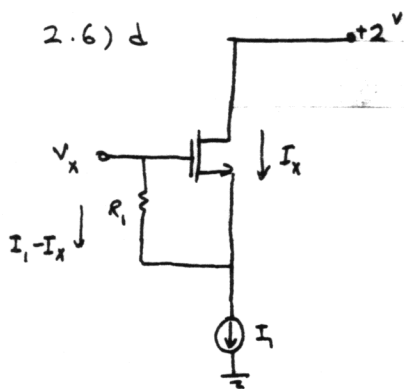
Then device enters the Saturation region;  $V_{GS} = 2 - V_x + R_1 (I_1 - I_x)$

$$I_x = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} [2 - V_x + R_1 (I_1 - I_x) - V_{TH}]^2$$

$$g_m = \mu_n C_{ox} \frac{W}{L} [2 - V_x + R_1 (I_1 - I_x) - V_{TH}]$$

Then device turns off when  $V_x = 2 - V_{TH} + R_1 I_1$





Assumption:  $R_i I_1 > V_{TH}$

for  $0 < V_x < 2 + V_{TH}$  : Device is in the saturation region

$$V_{GS} = R_i (I_1 - I_x)$$

$$I_D = I_x = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} [R_i (I_1 - I_x) - V_{TH}]^2$$

$I_x$  is a constant that can be derived by solving the above equation.

Then device enters the triode region for  $V_x > 2 + V_{TH}$

In this case  $V_{GS} = R_i (I_1 - I_x)$   $V_{DS} = 2 - [V_x - R_i (I_1 - I_x)] = 2 - V_x + R_i (I_1 - I_x)$

$$I_x = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} [2(V_{GS} - V_{TH})V_{DS} - V_{DS}^2] = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} [2[R_i(I_1 - I_x) - V_{TH}] - 2 + V_x - R_i(I_1 - I_x)] \times (2 - V_x + R_i(I_1 - I_x))$$

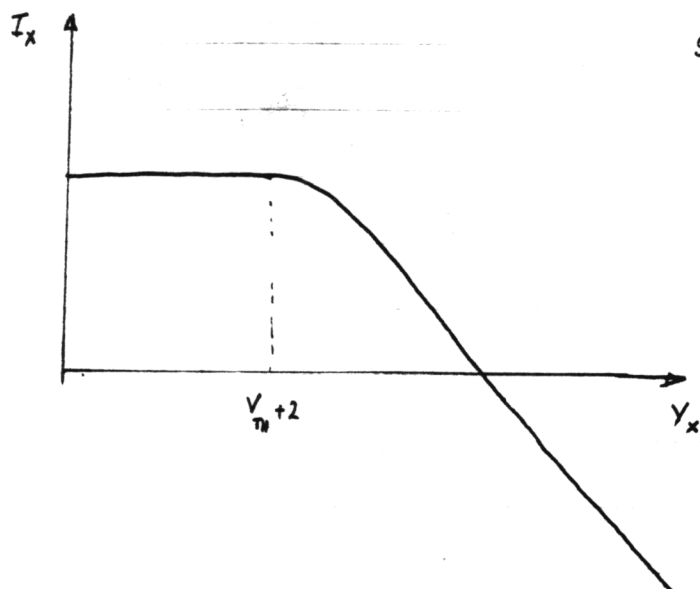
$$I_x = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} [(R_i(I_1 - I_x) - V_{TH}) + (V_x - 2 - V_{TH})][(R_i(I_1 - I_x) - V_{TH}) - (V_x - 2 - V_{TH})]$$

$$(*) \quad I_x = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} [(R_i(I_1 - I_x) - V_{TH})^2 - (V_x - 2 - V_{TH})^2]$$

The second term shows that  $I_x$  decreases when we increase  $V_x$

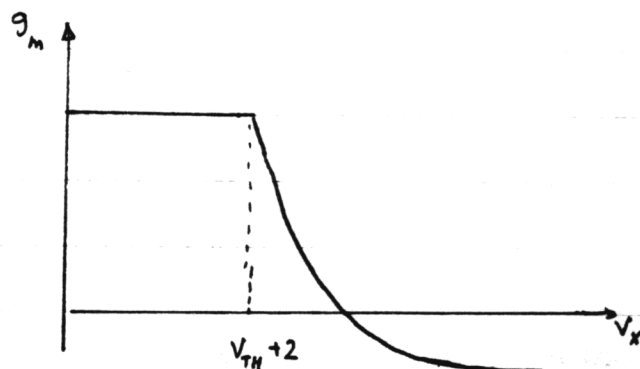
The polarity of  $I_x$  changes for higher  $V_x$  (Device still is in triode)

(\*) presents  $I_x - V_x$  relationship in this region.

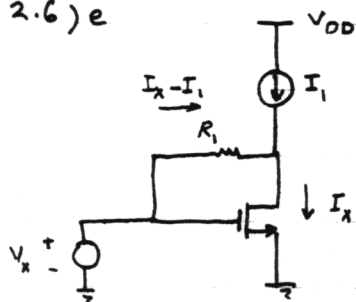


$$g_m = \mu_n C_{ox} \frac{W}{L} [R_1 (I_1 - I_x) - V_{TH}] \quad ; V_x < 2 + V_{TH}$$

$$g_m = \mu_n C_{ox} \frac{W}{L} V_{DS} = \mu_n C_{ox} \frac{W}{L} [R_1 (I_1 - I_x) + 2 - V_x] \quad V_x > 2 + V_{TH}$$



2.6) e



for  $0 < V_x < V_{TH}$  Device is off  $I_x = 0$   $g_m = 0$

Then device turns on (in the saturation region)

$$I_x = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_x - V_{TH})^2$$

Transistor is in the saturation until

$$V_{GD} = R_1 (I_x - I_1) = V_{TH} \text{ , Then device}$$

enters the triode region. (When  $I_x = I_1 + \frac{V_{TH}}{R_1}$  , i.e.  $V_x = V_{TH} + \sqrt{\frac{2I_1 + 2V_{TH}/R_1}{\mu_n C_{ox} \frac{W}{L}}}$  )

$$\text{So, } V_{TH} < V_x < V_{TH} + \sqrt{\frac{2I_1 + 2V_{TH}/R_1}{\mu_n C_{ox} \frac{W}{L}}}$$

$$I_x = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_x - V_{TH})^2$$

$$g_m = \mu_n C_{ox} \frac{W}{L} (V_x - V_{TH})$$

2.6) e Cont.

Then device enters the triode region.

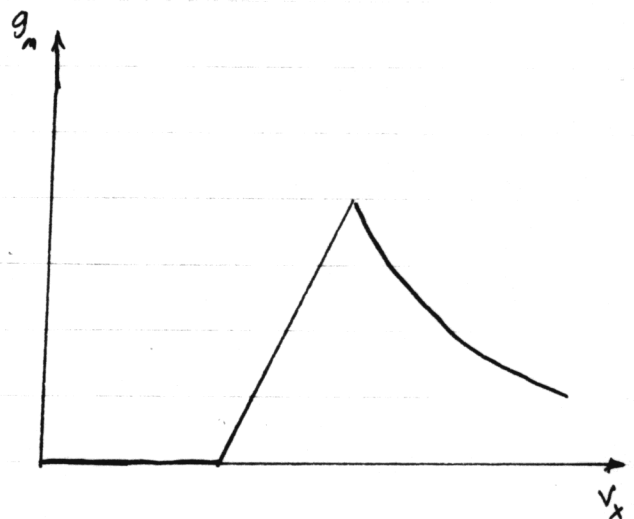
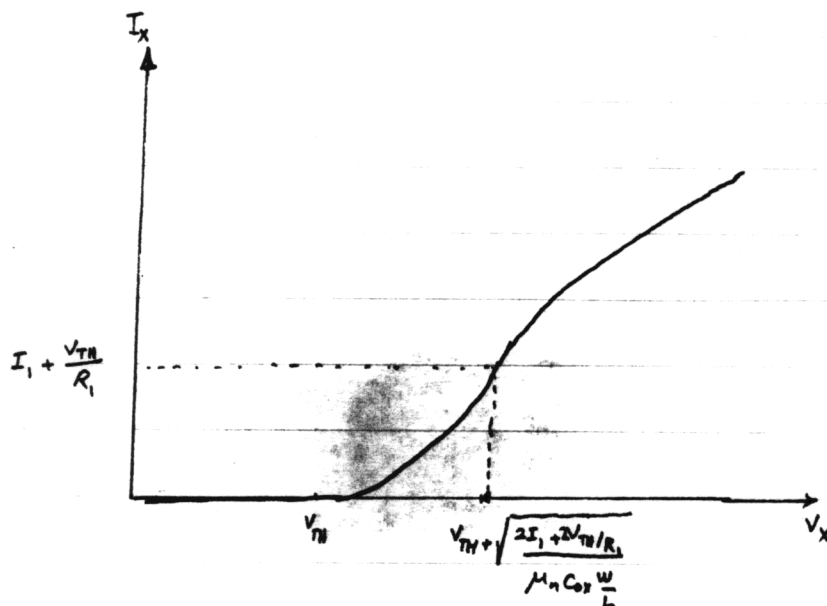
$$V_{GS} = V_X \quad V_{DS} = V_X - R_1(I_X - I_1)$$

$$I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \left[ 2(V_{GS} - V_{TH}) - V_{DS} \right] V_{DS} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \left[ 2(V_X - V_{TH}) - V_X + R_1(I_X - I_1) \right] (V_X - R_1(I_X - I_1))$$

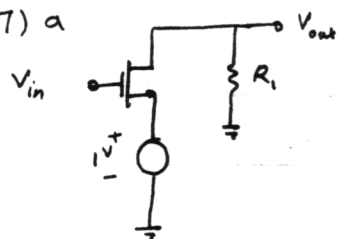
$$(*) \quad I_X = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_X + R_1(I_X - I_1) - 2V_{TH})(V_X - R_1(I_X - I_1))$$

The above equation presents  $I_X - V_X$  relationship in triode region.

$$\text{In this region, } g_m = \mu_n C_{ox} \frac{W}{L} V_{DS} = \mu_n C_{ox} \frac{W}{L} (V_X - R_1(I_X - I_1))$$



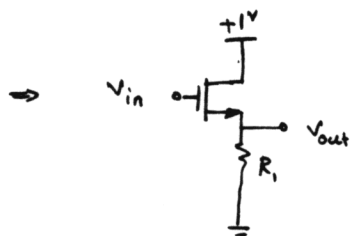
2.7) a



$$\lambda = \gamma = 0$$

$$V_{TH} = 0.7$$

Drain and source exchange their roles.



for  $0 < V_{in} < 0.7$  device is off  $V_{out} = 0$

for  $0.7 < V_{in} < 1.7$  device is in the saturation region

$$(*) \quad I_D = \frac{V_{out}}{R_1} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{in} - V_{out} - 0.7)^2 \Rightarrow \text{Input-Output relationship}$$

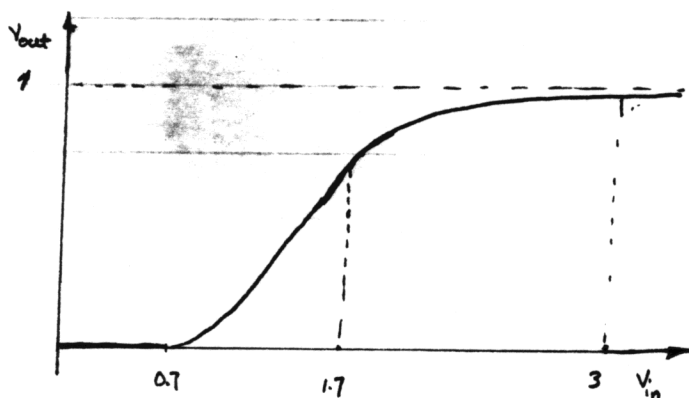
for  $1.7 < V_{in} < 3$  device is in the triode region

$$V_{GS} = V_{in} - V_{out}$$

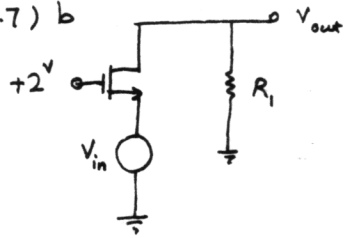
$$V_{DS} = 1 - V_{out}$$

$$(*) \quad I_D = \frac{V_{out}}{R_1} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \left[ 2(V_{in} - V_{out} - 0.7)(1 - V_{out}) - (1 - V_{out})^2 \right]$$

$\Rightarrow$  Input-output relationship

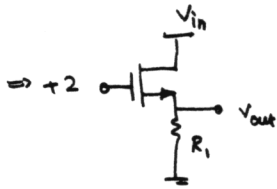


2.7) b



$$\gamma = \lambda = 0 \quad V_{TH} = 0.7$$

Drain and source exchange their roles!



for  $0 < V_{in} < 1.3$  device is in triode

$$V_{GS} = 2 - V_{out} \quad V_{DS} = V_{in} - V_{out}$$

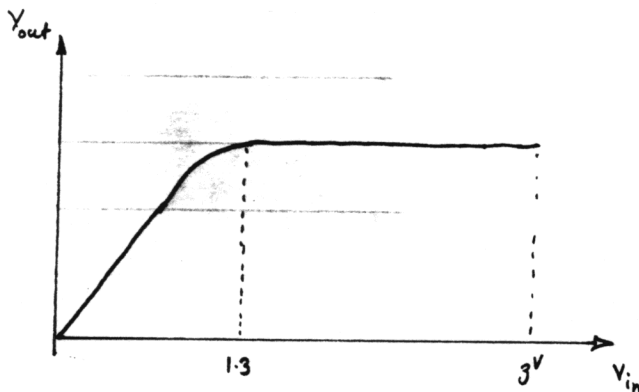
$$(*) \quad I_D = \frac{V_{out}}{R_1} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \left[ 2(2 - V_{out} - 0.7)(V_{in} - V_{out}) - (V_{in} - V_{out})^2 \right]$$

Input output relationship is presented by the above equation.

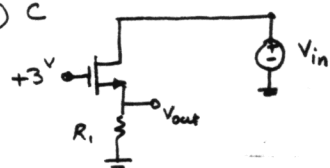
for  $1.3 < V_{in} < 3$  device is in the saturation region

$$I_D = \frac{V_{out}}{R_1} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (2 - V_{out} - 0.7)^2$$

$V_{out}$  doesn't depend on  $V_{in}$  and it is constant for  $V_{in} > 1.3$



2.7) c



$$\gamma = \lambda = 0 \quad V_{TH} = 0.7$$

for  $0 < V_{in} < 2.3$  device is in triode

$$V_{GS} = 3 - V_{out} \quad V_{DS} = V_{in} - V_{out}$$

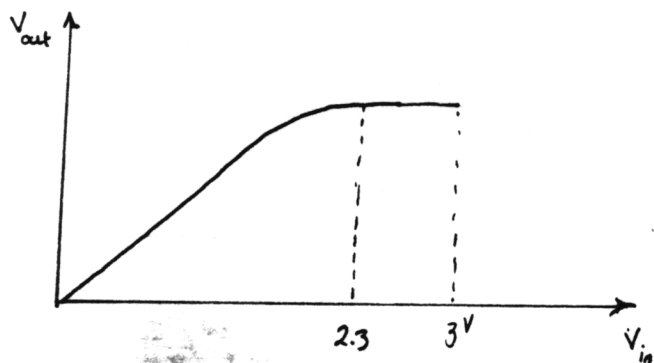
$$(*) \quad I_D = \frac{V_{out}}{R_1} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \left[ 2(3 - V_{out} - 0.7)(V_{in} - V_{out}) - (V_{in} - V_{out})^2 \right]$$

Input-output relationship is presented by the above equation.

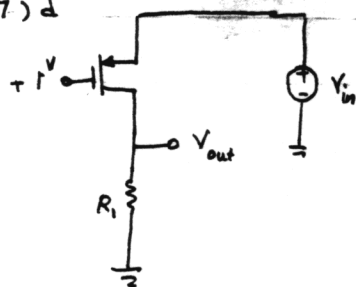
for  $2.3 < V_{in} < 3$  device is in the saturation region

$$I_D = \frac{V_{out}}{R_1} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (3 - V_{out} - 0.7)^2$$

$V_{out}$  is constant for  $V_{in} > 2.3$  (It doesn't depend on  $V_{in}$ )



2.7) d



$$|V_{TH}| = 0.8$$

$$\gamma = \lambda = 0$$

for  $0 < V_{in} < 1.8$  device is off  $\Rightarrow V_{out} = 0$

Then device turns on (in sat.) and  $V_{out}$  goes up

until  $V_{out} = 1.8$ , then device enters the triode region

for  $V_{in} > 1.8$  and  $V_{out} < 1.8$

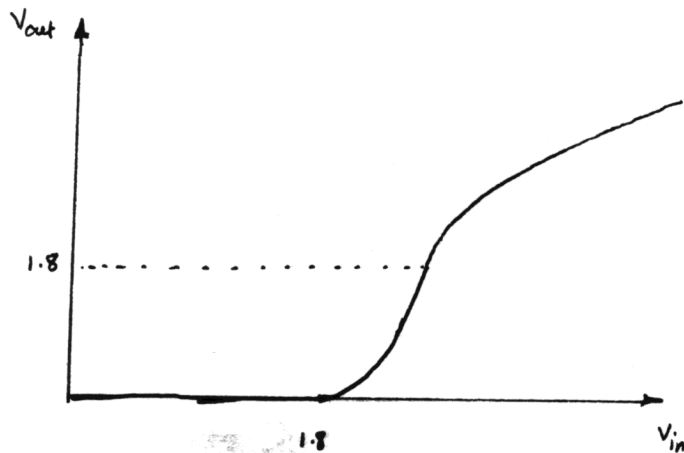
$$I_D = \frac{V_{out}}{R_1} = \frac{1}{2} \mu_p C_{ox} \frac{W}{L} (V_{in} - 1.8)^2 \Rightarrow V_{out} = \frac{1}{2} \mu_p C_{ox} R_1 \frac{W}{L} (V_{in} - 1.8)^2$$

This is good for  $1.8 < V_{in} < 1.8 + \sqrt{\frac{2 \times 1.8 V}{\mu_p C_{ox} \frac{W}{L} R_1}}$

for  $V_{in} > 1.8 + \sqrt{\frac{2 \times 1.8 V}{\mu_p C_{ox} \frac{W}{L} R_1}}$

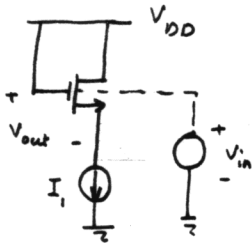
$$I_D = \frac{V_{out}}{R_1} = \frac{1}{2} \mu_p C_{ox} \frac{W}{L} \left[ 2 (V_{in} - 1.8) (V_{in} - V_{out}) - (V_{in} - V_{out})^2 \right]$$

Input-output relationship is presented by the above equation.





2.8) a



$$V_S = V_{DD} - V_{out}$$

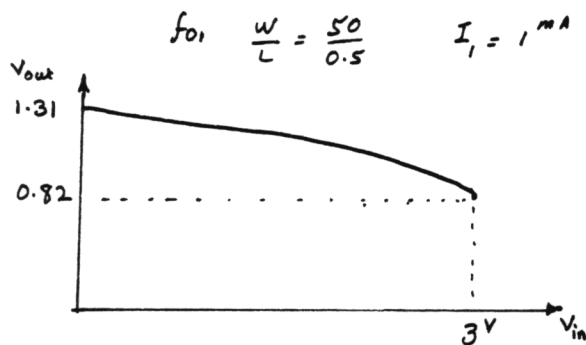
$$V_B = V_{in}, V_{SB} = V_{DD} - V_{out} - V_{in}$$

$$I_D = I_1 = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{out} - V_{TH})^2$$

$$V_{TH} = V_{TH0} + \gamma (\sqrt{2\phi_F + V_{SB}} - \sqrt{2\phi_F})$$

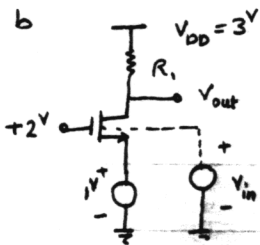
$$\Rightarrow I_1 = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{out} - V_{TH0} - \gamma (\sqrt{2\phi_F + V_{DD} - V_{out} - V_{in}} - \sqrt{2\phi_F}))^2$$

for each  $V_{in}$ , the above equation should be solved to obtain  $V_{out}$



$$\text{Assumption: } 2\phi_F + V_{DD} - V_{out} - V_{in} > 0$$

2.8) b



$$V_{SB} = 1 - V_{in}$$

$$V_{GS} = 1$$

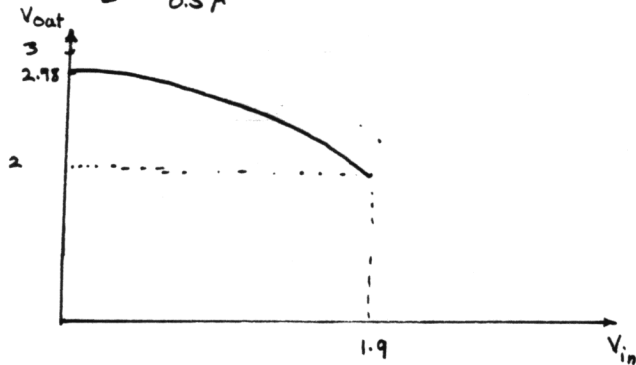
$$V_{TH} = V_{TH0} + \gamma (\sqrt{2\phi_F + V_{SB}} - \sqrt{2\phi_F})$$

$$V_{TH} = 0.7 + 0.45 (\sqrt{1.9 - V_{in}} - \sqrt{0.9})$$

Assumption:  $V_{in}$  varies from 0 to 1.9 and  $R_1$  is small enough to guarantee that the device remains in the saturation region.

$$V_{out} = 3 - R_1 \cdot \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (0.3 - 0.45 (\sqrt{1.9 - V_{in}} - \sqrt{0.9}))^2$$

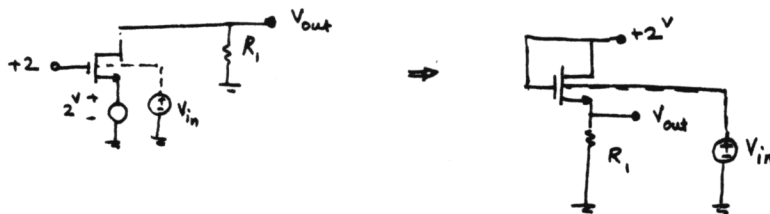
for  $\frac{W}{L} = \frac{50 \mu}{0.5 \mu}$ ,  $R = 0.2 \text{ K}$



2.8) C

Drain and Source exchange their roles ,

$V_{TH0} = 0.7$   $\gamma = 0.45$   $2\phi_F = 0.9$



Assumption :  $V_{SB} > -2\phi_F$  ( $V_{out} - V_{in} > -2\phi_F$ )  $\Rightarrow$  Device is in the Saturation

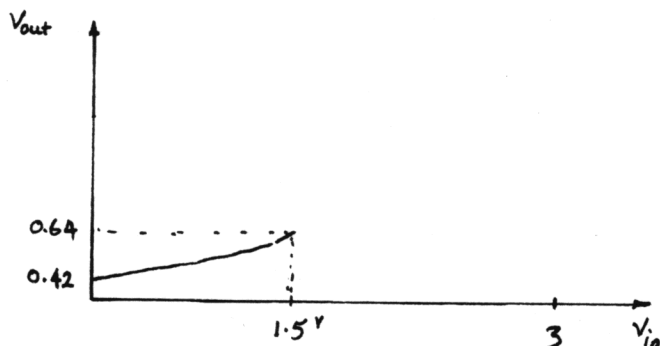
$$V_{TH} = 0.7 + 0.45 (\sqrt{0.9 + V_{out} - V_{in}} - \sqrt{0.9}) \quad V_{GS} = 2 - V_{out}$$

$$I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (2 - V_{out} - 0.7 - 0.45 (\sqrt{0.9 + V_{out} - V_{in}} - \sqrt{0.9}))^2$$

$$I_D = \frac{V_{out}}{R_i}$$

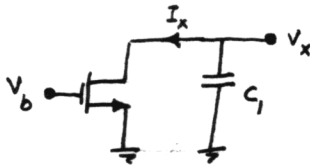
$$(*) \quad \frac{V_{out}}{R_i} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (2 - V_{out} - 0.7 - 0.45 (\sqrt{0.9 + V_{out} - V_{in}} - \sqrt{0.9}))^2$$

Input-Output relationship is presented by the above equation.



$\frac{W}{L} = \frac{50}{0.5}$   $R = 100 \Omega$

2.9) a



$$\gamma = \lambda = 0$$

$$V_{TH} = 0.7$$

for  $V_b - 0.7 < V_x < 3$  device is in saturation

Assume  $V_b > V_{TH}$

$$I_x = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_b - V_{TH})^2$$

$$V_x = -\frac{1}{C_1} \int I_x dt + 3^V = 3 - \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_b - V_{TH})^2 t$$

Then device goes into triode, for  $0 < V_x < V_b - 0.7$

$$I_x = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} [2(V_b - 0.7)V_x - V_x^2] = -\frac{dV_x}{dt} \times C_1$$

$$\Rightarrow -dt \underbrace{\frac{1}{2} \mu_n C_{ox} \frac{W}{L} \times \frac{1}{C_1}}_{\alpha} = \frac{dV_x}{V_x [2(V_b - 0.7) - V_x]}$$

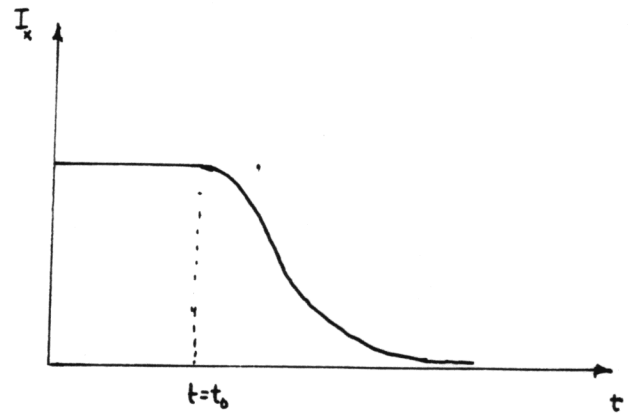
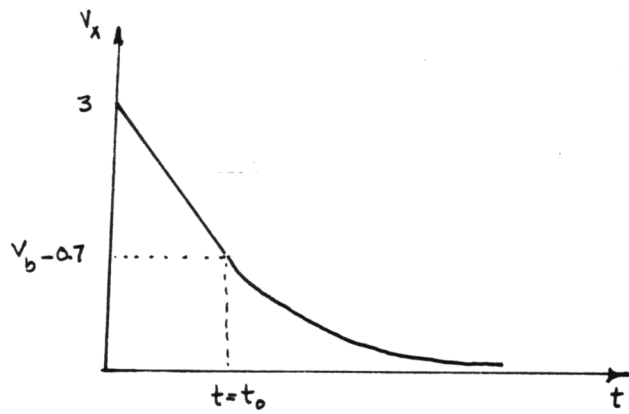
$$- \alpha dt = \left[ \frac{1}{V_x} + \frac{1}{2(V_b - 0.7) - V_x} \right] \times \frac{1}{2(V_b - 0.7)}$$

$$\Rightarrow -\alpha(t - t_0) = \left[ \ln \frac{V_x}{2(V_b - 0.7) - V_x} \right] \cdot \frac{1}{2(V_b - 0.7)} \quad @t=t_0, V_x = V_b - 0.7$$

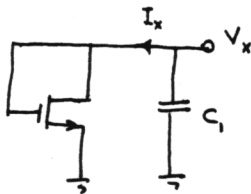
$$\Rightarrow \frac{2(V_b - 0.7) - V_x}{V_x} = e^{2\alpha(V_b - 0.7)(t - t_0)}$$

$$\Rightarrow V_x = \frac{2(V_b - 0.7)}{1 + e^{2\alpha(V_b - 0.7)(t - t_0)}}$$

$$I_x = -C_1 \frac{dV_x}{dt} = \frac{4\alpha C_1 (V_b - 0.7)^2 e^{2\alpha(V_b - 0.7)(t - t_0)}}{\left(1 + e^{2\alpha(V_b - 0.7)(t - t_0)}\right)^2}$$



2.9) b



Device is always in the saturation region.

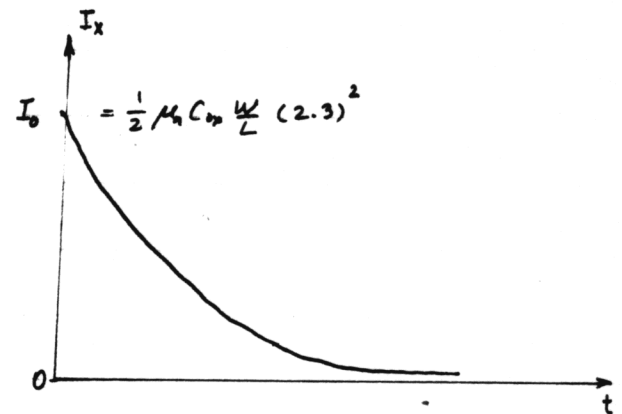
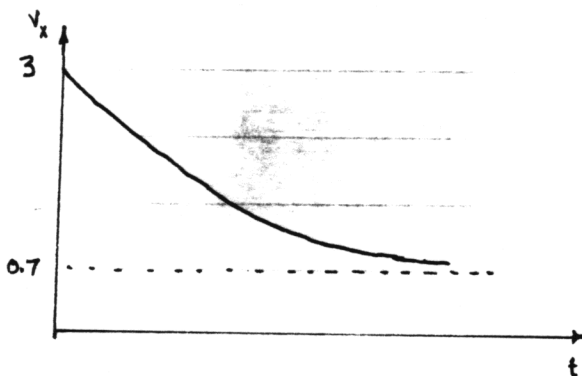
$$I_x = -C_1 \frac{dV_x}{dt} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_x - 0.7)^2$$

$$\Rightarrow \underbrace{\frac{1}{2} \mu_n C_{ox} \frac{W}{L} \frac{1}{C_1}}_{\alpha} dt = - \frac{dV_x}{(V_x - 0.7)^2}$$

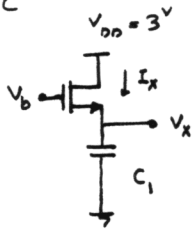
$$\Rightarrow \alpha t = \frac{1}{V_x - 0.7} + K$$

$$@ t=0, V_x = 3 \Rightarrow \alpha t = \frac{1}{V_x - 0.7} - \frac{1}{2.3} \Rightarrow V_x = 0.7 + \frac{1}{\alpha t + 1/2.3}$$

$$I_x = -C_1 \frac{dV_x}{dt} = \frac{\alpha C_1}{(\alpha t + \frac{1}{2.3})^2}$$

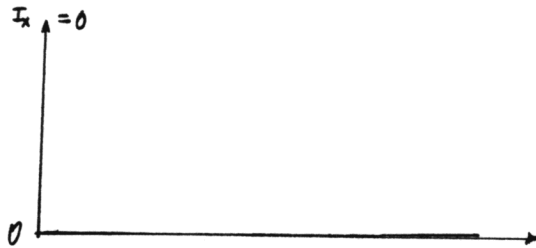
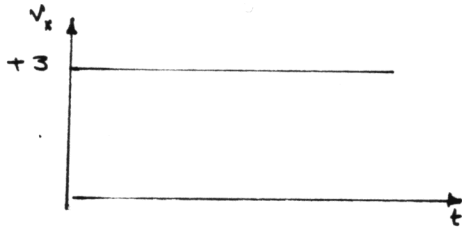


2.9) c

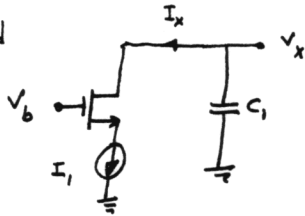


$$\text{@ } t=0 \quad V_x = 3, V_{op} = 3^V \Rightarrow V_{os} = 0 \Rightarrow I_x = 0$$

And the circuit remains in this state



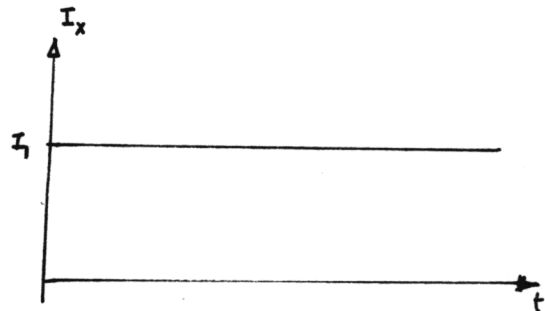
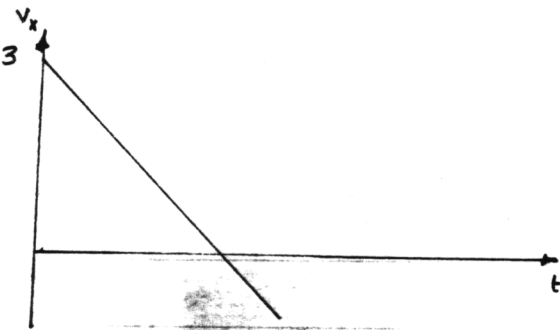
2.9) d



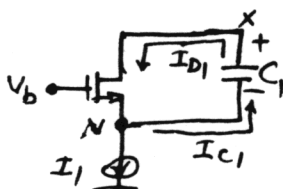
$$I_x = I_1$$

$$-C_1 \frac{dV_x}{dt} = I_1 \Rightarrow V_x = 3 - \frac{I_1}{C} t$$

In fact these Equations are valid until  $I_1$  is no longer an ideal current source.



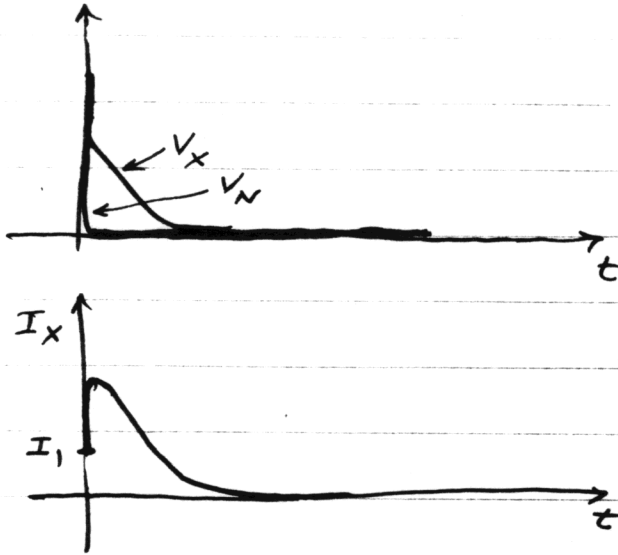
2.9) e Initially, the current thru  $M_1 = I_1 \Rightarrow$  certain  $V_{gs}$  is developed and  $V_x = V_b - V_{gs1} + 3V$  and  $I_x = I_1$ . However, at  $t=0^+$ , the drain current of  $M_1$  flows from  $C_1$ :  $I_{D1} - I_{C1} = I_1$ . But,



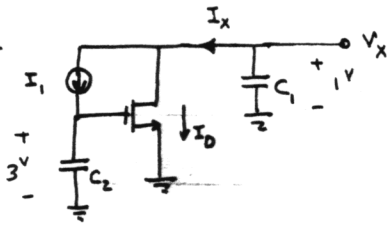
$I_{D1} = I_{C1} \Rightarrow I_1 = 0$ . If the current source is ideal,  $V_x$  jumps to  $-\infty$  (actually about 0.6V below 0, where the S-B diode turns on.)

If  $I_1$  is not ideal,  $V_x$  jumps to zero and  $C_1$  discharges

2.9) e (cont'd)

through  $M_1$ :

2.10) a

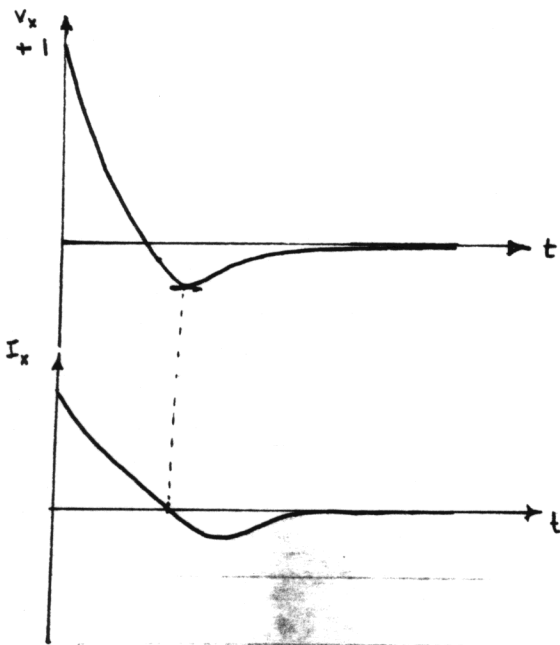


$$V_G = 3 + \frac{I_1 t}{C}$$

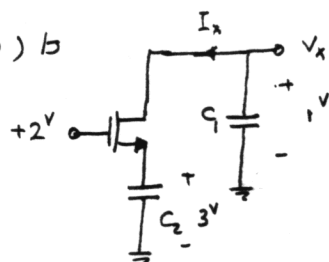
This circuit settles at  $t = \infty$ , when  $V_G = \infty$   
 $I_D = -I_1$ ,  $V_{DS} = 0$  (Actually, Drain and Source exchange their roles after a specific time at which  $I_x = I_1$  and afterward  $V_x$  becomes negative) However, transistor always operates in the triode region.

$$I_x = I_1 + \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \left[ 2 \left( 3 + \frac{I_1}{C_2} t - 0.7 \right) V_x - V_x^2 \right] = -C_1 \frac{dV_x}{dt}$$

The values of  $V_x$  can be obtained by numerical methods



2.10) b



Drain and source exchange their roles.

$$(\gamma = \lambda = 0) \quad V_{TH} = 0.7$$

$$\int I_D dt = q \quad V_X = 1 + \frac{q}{C_1} \quad , \quad V_D = V_{C_2} = 3 - \frac{q}{C_2}$$

 $V_X$  goes up until transistor turns off when  $V_X = 1.3$ 

Assumption: Transistor is in saturation.

This assumption is correct if:  $V_D = 3 - \frac{q}{C_2} > 1.3 \quad (2 - 0.7)$ 

$$V_X(\infty) = 1 + \frac{q(\infty)}{C_1} = 1.3$$

$$V_D(\infty) = 3 - \frac{q(\infty)}{C_2} = 3 - 0.3 \frac{C_1}{C_2} > 1.3$$

$$0.3 \frac{C_1}{C_2} < 1.7$$

$$C_1 < 5.67 C_2$$

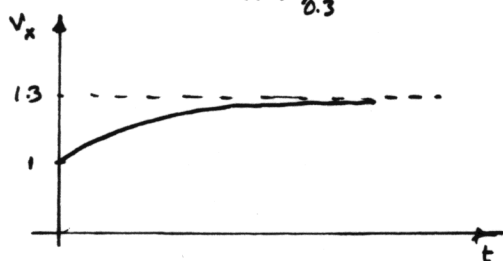
$$I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \left( 2 - 1 - \frac{q}{C_1} - 0.7 \right)^2 = \frac{dq}{dt}$$

$$\Rightarrow \underbrace{\frac{1}{2} \mu_n C_{ox} \frac{W}{L} \frac{1}{C_1}}_{\alpha} dt = \frac{dq/C_1}{(0.3 - q/C_1)^2} \quad \Rightarrow \alpha t = \frac{1}{0.3 - q/C_1} + K \quad (t=0, q=0)$$

$$\Rightarrow \alpha t = \frac{1}{0.3 - q/C_1} - \frac{1}{0.3} \quad \Rightarrow \quad \frac{q}{C_1} = 0.3 - \frac{1}{\alpha t + \frac{1}{0.3}} \quad V_X = 1 + \frac{q}{C_1}$$

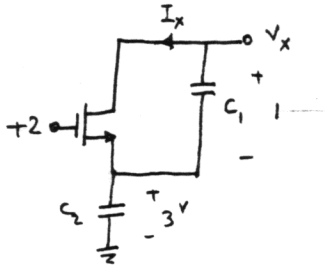
$$\Rightarrow V_X = 1.3 - \frac{1}{\alpha t + \frac{1}{0.3}}$$

$$I_X = -C_1 \frac{dV_X}{dt} = \frac{-\alpha C_1}{(\alpha t + \frac{1}{0.3})^2}$$





2.10) c

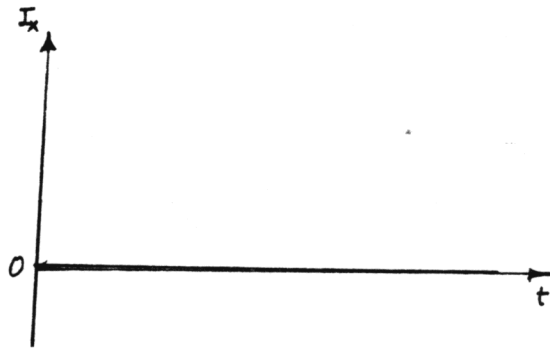
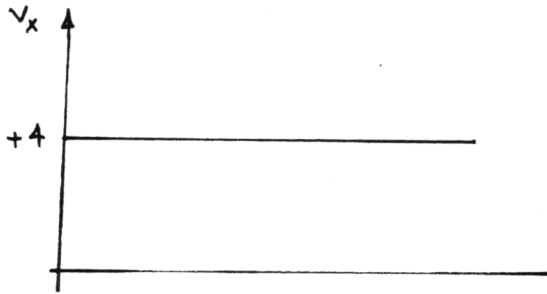


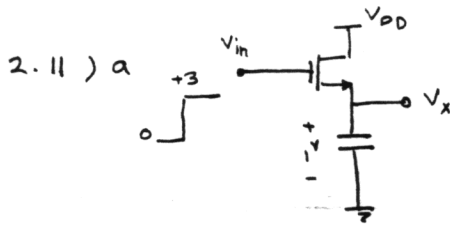
$$\text{At } t=0 \quad V_G = 2 \quad V_S = 3 \quad V_D = 4$$

Device is off and doesn't turn on.

The Circuit remains in this state.

$$\text{So, } V_x = 4 \quad I_x = 0$$





$$\gamma = \lambda = 0$$

$$V_{TH} = 0.7$$

At  $t=0^+$ , device turns on (in Sat) and starts charging the capacitor, until device turns off when;  $V_x = V_{in} - V_{TH} = 3 - 0.7 = 2.3$

$$I_c = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (2.3 - V_x)^2$$

$$; V_{GS} = 3 - V_x - 0.7$$

$$I_c = C_1 \frac{dV_x}{dt}$$

$$\Rightarrow \underbrace{\frac{1}{2} \mu_n C_{ox} \frac{W}{L} \times \frac{1}{C_1}}_{\alpha} (2.3 - V_x)^2 = \frac{dV_x}{dt}$$

$$\Rightarrow \alpha dt = \frac{dV_x}{(2.3 - V_x)^2}$$

$$\Rightarrow \alpha t + K_0 = \frac{1}{2.3 - V_x}$$

$$(t=0, V_x=1)$$

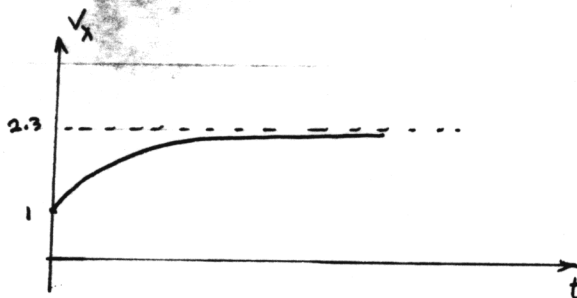
$$\alpha \times 0 + K_0 = \frac{1}{2.3 - 1}$$

$$\Rightarrow K_0 = 1/1.3$$

$$\Rightarrow \frac{1}{1.3} + \alpha t = \frac{1}{2.3 - V_x}$$

$$\Rightarrow 2.3 - V_x = \frac{1}{\alpha t + 1/1.3}$$

$$\Rightarrow V_x = 2.3 - \frac{1}{\alpha t + 1/1.3}$$



2.11) b



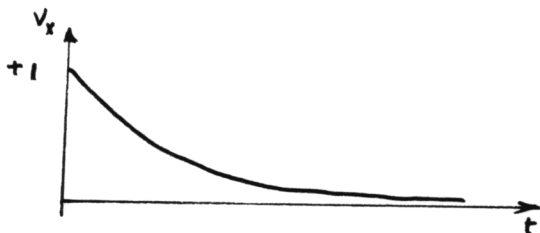
Transistor turns on at  $t=0$ , and discharges  $C_1$   
 Until  $V_x = 0$ , (device always operates in triode)

$$I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} [2(3-0.7)V_x - V_x^2] = -C_1 \frac{dV_x}{dt}$$

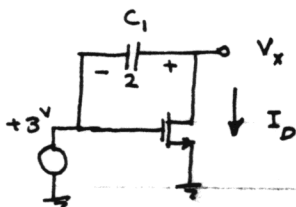
$$\underbrace{\frac{1}{2} \mu_n C_{ox} \frac{W}{L} \times \frac{1}{C_1}}_{\alpha} [4.6 V_x - V_x^2] = -\frac{dV_x}{dt} \Rightarrow -\alpha dt = \frac{dV_x}{V_x(4.6 - V_x)}$$

$$\Rightarrow -\alpha t = \left( \frac{1}{V_x} + \frac{1}{4.6 - V_x} \right) \frac{1}{4.6} + K, \quad @ t=0, V_x=1$$

$$\frac{1}{3.6} e^{-\alpha t} = \frac{V_x}{4.6 - V_x} \Rightarrow V_x = \frac{4.6}{1 + 3.6 e^{4.6 \alpha t}}$$



2.11) c



At  $t=0^+$ ,  $V_x = 5$ , device is in Saturation region

$$I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (3-0.7)^2, \quad V_x \text{ decreases until}$$

$V_x = 2.3$  at  $t=t_0$ , then device enters triode region

$$\text{for } t < t_0 \quad (V_x > 2.3) \quad V_x = 5 - \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (2.3)^2 \frac{t}{C_1}$$

$$\text{for } t > t_0 \quad I_D = -C_1 \frac{dV_x}{dt} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} [2(3-0.7)V_x - V_x^2]$$

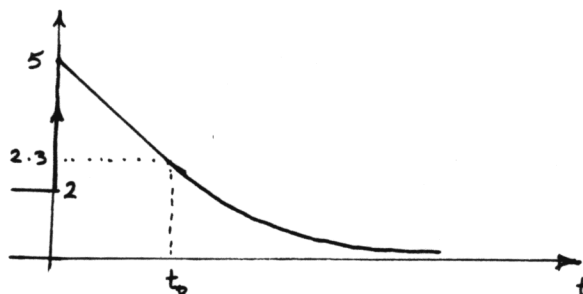
$$\Rightarrow \frac{dV_x}{V_x(4.6 - V_x)} = - \underbrace{\frac{1}{2} \mu_n C_{ox} \frac{W}{L} \cdot \frac{1}{C_1}}_{\alpha} dt$$

2.11) c, Cont.

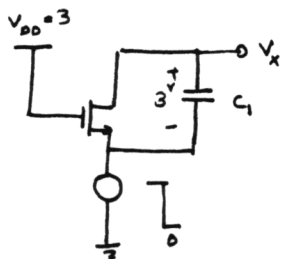
$$-\alpha(t-t_0) = \left[ \ln \frac{V_x}{4.6 - V_x} \right] \cdot \frac{1}{4.6}$$

$$t=t_0, V_x = 2.3$$

$$\Rightarrow V_x = \frac{4.6}{1 + e^{4.6 \alpha (t-t_0)}}$$



2.11) d

At  $t=0^+$ ,  $V_x = 3$  device is in saturation

$$I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (3 - 0.7)^2, V_x \text{ decreases until}$$

 $V_x = 2.3$  at  $t=t_0$ , then device enters triode region.for  $t < t_0$ 

$$V_x = 3 - \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (2.3)^2 \frac{t}{C_1}; \quad 2.3 < V_x < 3$$

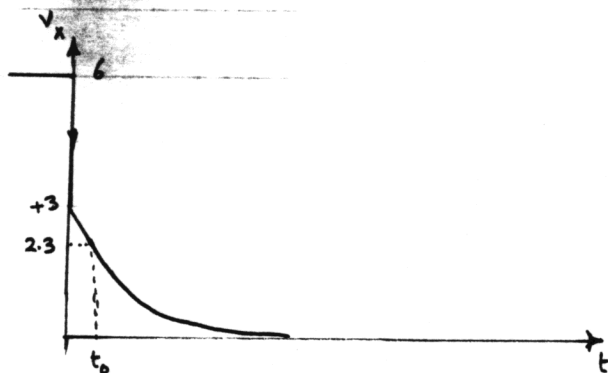
for  $t > t_0$ 

$$I_D = -C_1 \frac{dV_x}{dt} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} [2(3 - 0.7)V_x - V_x^2]$$

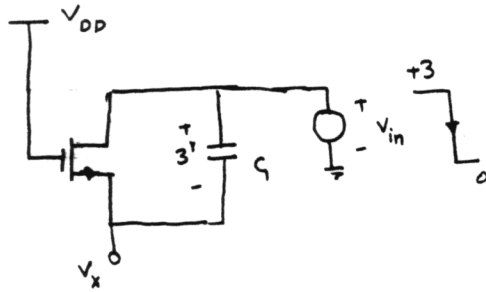
$$\frac{dV_x}{V_x(4.6 - V_x)} = -\frac{1}{2} \mu_n C_{ox} \frac{W}{L} \frac{1}{C_1} dt, \quad (t=t_0, V_x = 2.3)$$

$$-\alpha(t-t_0) = \left[ \ln \frac{V_x}{4.6 - V_x} \right] \frac{1}{4.6}$$

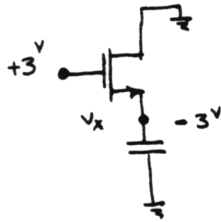
$$\Rightarrow V_x = \frac{4.6}{1 + e^{4.6 \alpha (t-t_0)}}$$



2.12) a)



Device is in the triode region.

 $t \geq 0^+$ 

$$I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \left[ 2(2.3 - V_x)(-V_x) - V_x^2 \right]$$

$$\begin{cases} V_{GS} = 3 - V_x \\ V_{DS} = -V_x \end{cases}$$

$$I_D = C_1 \frac{dV_x}{dt}$$

$$\Rightarrow \underbrace{\frac{1}{2} \mu_n C_{ox} \frac{W}{L} \times \frac{1}{C_1}}_{\alpha} \left[ V_x^2 - 4.6 V_x \right] = \frac{dV_x}{dt}$$

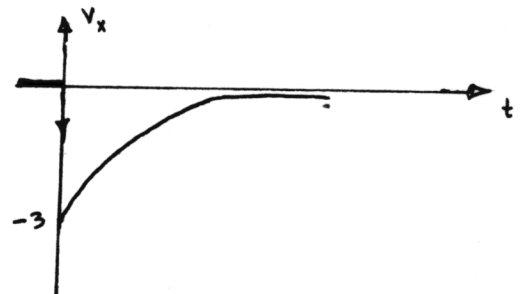
$$\Rightarrow \alpha dt = \frac{dV_x}{V_x^2 - 4.6 V_x} = dV_x \left( \frac{1}{V_x - 4.6} + \frac{-1}{V_x} \right) \times \frac{1}{4.6}$$

$$\Rightarrow 4.6 dt + K_0 = \ln \left( \frac{V_x - 4.6}{V_x} \right) \quad ; \quad V_x(0^+) = -3$$

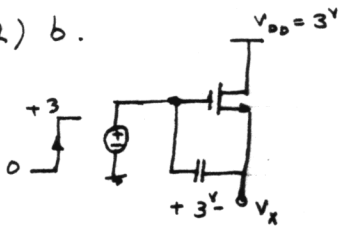
$$\Rightarrow K_0 = \ln \frac{7.6}{3} \quad \Rightarrow \frac{V_x - 4.6}{V_x} = \frac{7.6}{3} e^{4.6 \alpha t}$$

$$\Rightarrow \frac{4.6}{V_x} = 1 - \frac{7.6}{3} e^{4.6 \alpha t}$$

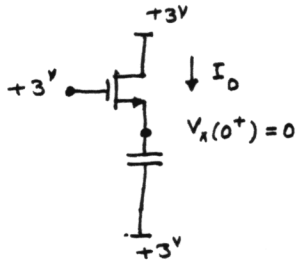
$$\Rightarrow V_x = \frac{-4.6}{\frac{7.6}{3} e^{4.6 \alpha t} - 1}$$



2.12) b.



Device is in saturation region

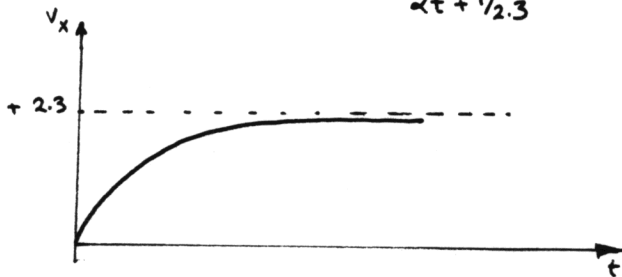
 $t = 0^+$ 

$$I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (3 - V_x - 0.7)^2 = C_1 \frac{dV_x}{dt}$$

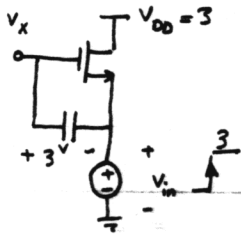
$$\frac{dV_x}{(2.3 - V_x)^2} = \underbrace{\frac{1}{2} \mu_n C_{ox} \frac{W}{L} \cdot \frac{1}{C_1}}_{\alpha} dt$$

$$\Rightarrow \frac{1}{2.3 - V_x} = \alpha t + K \quad (t=0, V_x=0) \Rightarrow \frac{1}{2.3 - V_x} - \frac{1}{2.3} = \alpha t$$

$$\Rightarrow V_x = 2.3 - \frac{1}{\alpha t + 1/2.3}$$



2.12) c

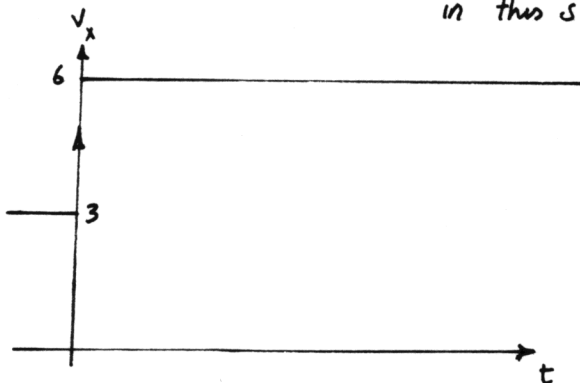


$$\text{At } t=0^+ \quad V_D = 3 \quad V_S = 3 \quad V_G = 6$$

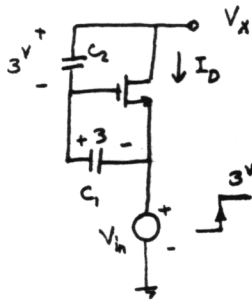
So,  $V_{GS} = 0$  and  $I_G = I_D = 0$  And circuit remains

in this state.

$$V_x(0^-) = 3, \quad V_x(t) = 6$$



2.12) d



Assume that the device remains in the saturation region until it turns off when  $V_{gs} = 0.7$

$$V_{c1} = V_{gs} = 3 - \frac{1}{C_1} \int I_D dt \quad V_{c2} = V_{dg} = 3 - \frac{1}{C_2} \int I_D dt$$

This assumption is correct if  $V_{dg} > -0.7$  when  $V_{gs} = 0.7$

$$\int I_D dt = q(t) \quad V_{gs} = 3 - \frac{q}{C_1} = 0.7 \Rightarrow \frac{q}{C_1} = 2.3 \quad V_{dg} = 3 - \frac{q}{C_2} > -0.7$$

$$\Rightarrow \frac{q}{C_2} < 3.7 \quad 2.3 \frac{C_1}{C_2} < 3.7 \Rightarrow C_1 < 1.61 C_2$$

With this assumption,

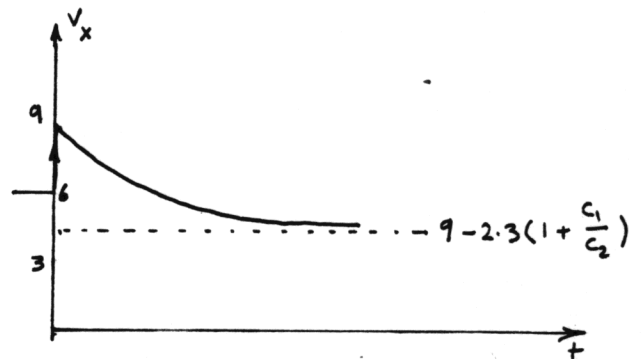
$$I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \left( 3 - \frac{q}{C_1} - 0.7 \right)^2 = \frac{dq}{dt}$$

$$\Rightarrow \underbrace{\frac{1}{2} \mu_n C_{ox} \frac{W}{L} \cdot \frac{1}{C_1}}_{\alpha} dt = \frac{dq/C_1}{\left( 3 - \frac{q}{C_1} - 0.7 \right)^2} \Rightarrow \alpha t = \frac{1}{3 - \frac{q}{C_1} - 0.7} + K \quad (t=0, q=0)$$

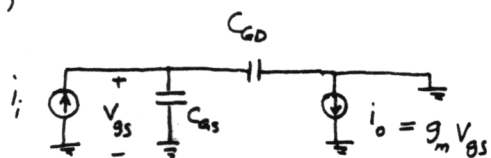
$$\Rightarrow \alpha t = \frac{1}{2.3 - \frac{q}{C_1}} - \frac{1}{2.3} \Rightarrow \frac{q}{C_1} = 2.3 - \frac{1}{\alpha t + 1/2.3}$$

$$V_x = 3 + 3 - \frac{q}{C_1} + 3 - \frac{q}{C_2} = 9 - \frac{q}{C_1} \left( 1 + \frac{C_1}{C_2} \right)$$

$$V_x(t) = 9 - \left( 1 + \frac{C_1}{C_2} \right) \frac{2.3 \alpha t}{\alpha t + 1/2.3}$$



2.13) a)



$$i_i = (C_{gs} + C_{gd}) s V_{gs}$$

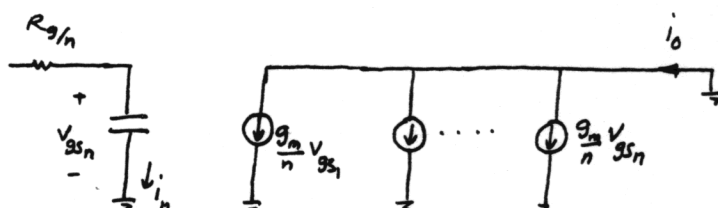
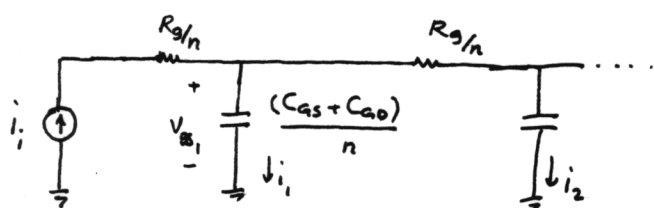
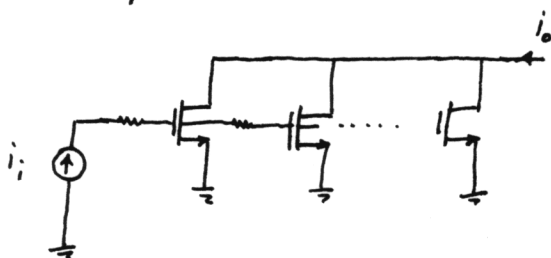
$$i_o = g_m V_{gs}$$

$$\beta = \frac{i_o}{i_i} = \frac{g_m}{(C_{gs} + C_{gd}) s} ; |\beta| = 1 \Rightarrow \frac{g_m}{(C_{gs} + C_{gd}) \omega_T} = 1$$

$$\Rightarrow \omega_T = \frac{g_m}{(C_{gs} + C_{gd})} \Rightarrow f_T = \frac{\omega_T}{2\pi} = \frac{g_m}{2\pi (C_{gs} + C_{gd})}$$

Approximation:  $g_m V_{gs}$  is the output current.

b)



$$i_k = \frac{1}{n} (C_{gs} + C_{gd}) s V_{gsk} \quad k = 1 \dots n$$

$$(*) \quad i_i = i_1 + i_2 + \dots + i_n = \frac{1}{n} (C_{gs} + C_{gd}) s (V_{gs1} + V_{gs2} + \dots + V_{gsn})$$

$$(**) \quad i_o = \frac{g_m}{n} V_{gs1} + \dots + \frac{g_m}{n} V_{gsn} = \frac{g_m}{n} (V_{gs1} + V_{gs2} + \dots + V_{gsn})$$

$$(*), (**) \Rightarrow \beta = \frac{i_o}{i_i} = \frac{g_m}{(C_{gd} + C_{gs}) s} ; |\beta| = 1 \Rightarrow f_T = \frac{\omega_T}{2\pi} = \frac{g_m}{2\pi (C_{gs} + C_{gd})}$$



$$c) \quad f_T = \frac{g_m}{2\pi (C_{GS} + C_{GD})}$$

$$g_m = \mu C_{ox} \frac{W}{L} (V_{GS} - V_{TH})$$

$$C_{GS} + C_{GD} \approx C_{ox} WL$$

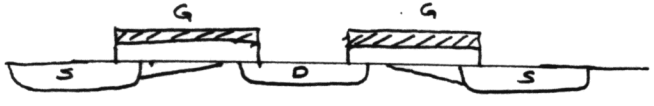
$$\Rightarrow f_T = \frac{\mu C_{ox} \frac{W}{L} (V_{GS} - V_{TH})}{2\pi C_{ox} WL} \approx \frac{\mu}{2\pi} \frac{(V_{GS} - V_{TH})}{L^2}$$

2.14)

$$f_T = \frac{g_m}{2\pi (C_{GS} + C_{GD})} ; \quad g_m = \frac{I_D}{5V_T}$$

In the subthreshold  $C_{GS} = C_{GD} = WC_{ov}$  (Fig 2.1.33)

$$\text{So, } f_T = \frac{I_D / 5V_T}{4\pi WC_{ov}} = \frac{I_D}{4\pi 5V_T WL_D C_{ox}}$$

2.15)   $\begin{cases} C_{j0} = 0.56 \times 10^{-3} \text{ F/m}^2 \\ m_j = 0.6 \end{cases} \quad \begin{cases} C_{jsw0} = 0.35 \times 10^{-11} \text{ F/m} \\ m_{jsw} = 0.2 \end{cases}$

$$C_{DB} = \frac{W}{2} E C_j + 2 \left( \frac{W}{2} + E \right) C_{jsw}$$

$$C_j = \frac{C_{j0}}{\left(1 + \frac{V_A}{2\phi_F}\right)^m}$$

$$C_{SB} = 2 \left[ \frac{W}{2} E C_j' + 2 \left( \frac{W}{2} + E \right) C_{jsw}' \right]$$

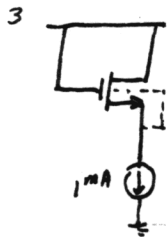
$$C_{GD} = 2 \left( \frac{W}{2} C_{ov} \right)$$

$$C_{ov} = L_D C_{ox}$$

$$C_{GS} = \frac{2WL C_{ox}}{3} + WC_{ov}$$

$$C_{GB} = (WL C_{ox}) C_d / (WL C_{ox} + C_d) ; C_d = WL \sqrt{q \epsilon_{si} N_{sub} / 2 \phi_F}$$

$$W = 50 \mu \quad L = 0.5 \mu \quad E = 1.5 \mu$$



$$I = \frac{1}{2} \mu_n C_{ox} \frac{W}{L - 2L_D} (V_{GS} - V_{TH})^2, \quad 1 \text{ mA} = \frac{1}{2} \times 0.13429 \times \frac{50}{0.5 - 0.16} (V_{GS} - 0.7)^2$$

$$V_{GS} = 1.0182$$

$$g_m = \frac{2I_D}{V_{GS} - V_{TH}} = 6.285 \text{ mA/V}, \quad V_{DS} = 1.0182$$

$$\lambda = 0, \quad L_D = 0.08 \mu \text{m}$$

$$\frac{W}{L} = \frac{50 \mu}{0.5 \mu}, \quad V_{TH} = 0.7$$

$$C_{GD} = 15.4 \text{ fF}$$

$$C_{GS} = 79.36 \text{ fF}$$

$$\mu_n C_{ox} = 134.29 \text{ mA/V}^2$$

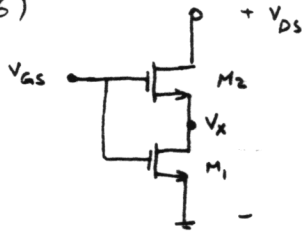
$$C_{ox} = 3.84 \times 10^{-3} \text{ F/m}^2$$

$$C_{SB} = 42.4 \text{ fF}$$

$$C_{DB} = 13.5 \text{ fF}$$

$$f_T = \frac{g_m}{2\pi(C_{GD} + C_{GS})} = 10.6 \text{ GHz}$$

2.16)

CASE I,  $M_1$ : Triode  $M_2$ : Triode

$$V_{GS1} = V_{GS} - V_{TH}$$

$$V_{GS2} = V_{GS} - V_X - V_{TH}$$

$$V_{DS1} = V_X$$

$$V_{DS2} = V_{DS} - V_X$$

$$I_{D1} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \left[ 2(V_{GS} - V_{TH}) V_X - V_X^2 \right] \quad (*)$$

$$I_{D2} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \left[ 2(V_{GS} - V_{TH} - V_X)(V_{DS} - V_X) - (V_{DS} - V_X)^2 \right]$$

$$I_{D1} = I_{D2} \Rightarrow 2(V_{GS} - V_{TH}) V_X - V_X^2 = 2(V_{GS} - V_{TH}) V_{DS} + 2V_X^2 - 2V_X(V_{GS} - V_{TH}) - 2V_X V_{DS} - V_{DS}^2 - V_X^2 + 2V_X V_{DS}$$

$$\Rightarrow 2 \left[ 2(V_{GS} - V_{TH}) V_X - V_X^2 \right] = 2(V_{GS} - V_{TH}) V_{DS} - V_{DS}^2 \quad (**)$$

$$(*), (**) \Rightarrow I_{D1} = I_{D2} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \times \frac{1}{2} \left[ 2(V_{GS} - V_{TH}) V_{DS} - V_{DS}^2 \right] \left( \frac{W}{2L} \text{ in Triode} \right)$$

CASE II,  $M_1$ : Triode,  $M_2$ : Sat

$$I_{D1} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \left[ 2(V_{GS} - V_{TH}) V_X - V_X^2 \right] \quad (*)$$

$$I_{D2} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{GS} - V_X - V_{TH})^2$$

$$I_{D1} = I_{D2} \Rightarrow V_X^2 - 2V_X(V_{GS} - V_{TH}) + (V_{GS} - V_{TH})^2 = 2(V_{GS} - V_{TH}) V_X - V_X^2$$

$$\Rightarrow (V_{GS} - V_{TH})^2 = 2 \left[ 2(V_{GS} - V_{TH}) V_X - V_X^2 \right] \quad (**)$$

2.16) Cont.  $(*) , (**) \Rightarrow I_{D1} = I_{D2} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \times \frac{1}{2} (V_{GS} - V_{TH})^2 \left( \frac{W}{2L} \text{ in Sat} \right)$

Note that  $M_1$  is always in triode, because  $V_{od2}$  is always positive

i.e.  $V_{GS2} - V_{TH} > 0 \Rightarrow V_{GS} - V_X - V_{TH} > 0 \Rightarrow V_{GS} - V_{TH} > V_X$

$\Rightarrow V_{GS1} - V_{TH} > V_{DS1} \Rightarrow M_1$  is in the triode region.

Saturation - triode transition edge of  $M_2$ :

We show that the transition point the saturation and triode region of the equivalent transistor is the same as that of  $M_2$ .

$$V_{od2} = V_{GS} - V_X - V_{TH} \quad V_{DS2} = V_{DS} - V_X$$

for  $V_{od2} > V_{DS2}$ ,  $M_2$  is in the triode region, i.e.  $V_{GS} - V_{TH} > V_{DS}$

It means that when  $M_2$  is in the saturation, then the equivalent

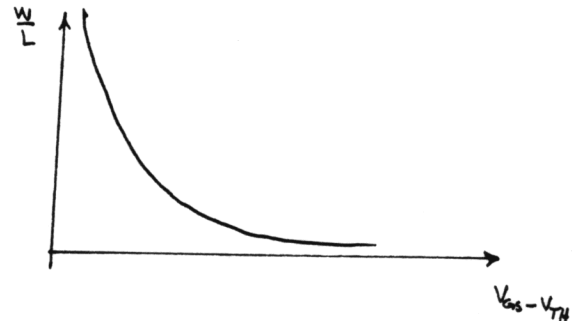
transistor is in the saturation, and vice versa.

2.17)

In Saturation region ,

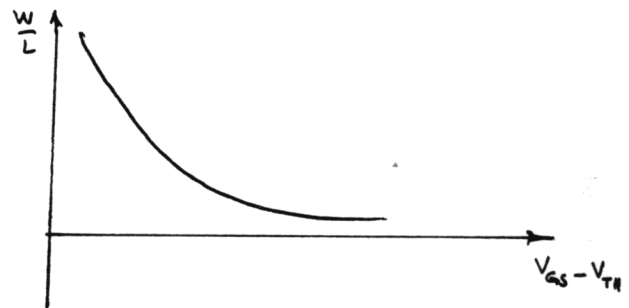
$$I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{GS} - V_{TH})^2$$

$$\Rightarrow \frac{W}{L} = \frac{2 I_D}{\mu_n C_{ox} (V_{GS} - V_{TH})^2}$$

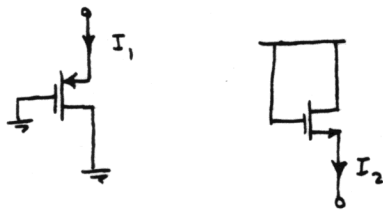


$$g_m = \mu_n C_{ox} \frac{W}{L} (V_{GS} - V_{TH})$$

$$\Rightarrow \frac{W}{L} = \frac{g_m}{\mu_n C_{ox} (V_{GS} - V_{TH})}$$



2.18)



These structures cannot operate as current sources, because

their currents strongly depend on source voltages, but

an ideal current source should provide a constant current,

independent of its voltage.

2.19) From Eq. (2.1) we know that  $V_{TH} = \phi_{MS} + 2\phi_F + \frac{Q_{dep}}{C_{ox}}$ , where

$\phi_{MS}$  and  $\phi_F$  are constant values, so any changes in  $V_{TH}$

come from the third term, in fact  $\Delta V_{TH} = \frac{\Delta Q_{dep}}{C_{ox}}$  and

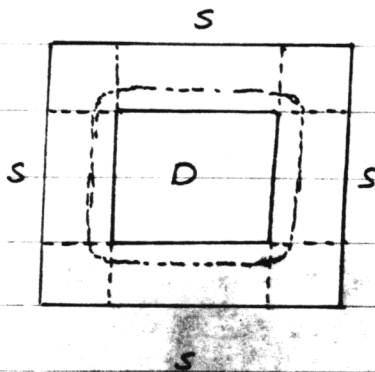
From Eq. (2.22), we have  $\Delta V_{TH} = \gamma (\sqrt{2\phi_F + V_{SB}} - \sqrt{2\phi_F})$  (in fact,

this is definition of  $\gamma$ ). from pn junction theory we know

that  $Q_{dep}$  is proportional to  $\sqrt{N_{sub}}$ , so  $\gamma$  is directly

proportional to  $\sqrt{N_{sub}}$  and inversely proportional to  $C_{ox}$ .

2.20)



This structure operates as a traditional device does, in fact if we neglect edges we have four MOSFETs in parallel,

where the aspect ratio of each is  $\frac{W}{L}$ .

So the overall aspect ratio is almost  $\frac{4W}{L}$ .

Drain junction capacitance:  $C_{DB} = W^2 C_j + 4WC_{jsw}$

Drain junction capacitance of devices shown in Fig. 2.32 a, b for the aspect ratio of  $\frac{4W}{L}$

$$C_{DB(a)} = 4WE C_j + (8W + 2E) C_{jsw}$$

$$C_{DB(b)} = 2WE C_j + (4W + 2E) C_{jsw}$$

The value of side wall capacitance in the ring structure is less than that in folded and traditional structures, but the bottom capacitance of ring structure

is higher than that of the other two structures. (for  $w > 4E$ )

2.21) We first check the terminals of the device with a multimeter

in order to find BS or BD junctions. There are 12 experiments

in total of which two lead to conduction and remaining ones show

no conduction. If we find one of those two conduction then we

are done. Finding B and S (or D), we need to do one other

experiment between B (Cathode of junction) and one of the two

remaining terminals; In case of no connection, the terminal under

test is G, otherwise it is D (or S). In worst case with a maximum

of 8 experiments, each terminal can be specified. It is as follows:

Assume, the two selected terminals do not conduct in both

directions and this is the case for the other two terminals.

Up to this point, four experiments have been done while not yet

encountering any conduction. It is clear that one group consists of

G and B and the other comprises from D and S, Because at least one conduction should be observed if B were in the same group with one of the source or Drain. In the next step, we pick up one terminal from each group to undergo the conductivity test. Assume, no conduction happens in either direction (Worst case). It means that we had chosen G from (GB) group. Thus far, we have done six experiments. We change both of terminals and now we have chosen B for sure. and in worst case, we will find a connection in 8th experiment. Now, we know B and S (D), Bulk's groupmate is Gate and Source's (Drain's) groupmate is Drain (Source).

2.22) If we don't know the type of device, In eight experiment we cannot distinguish between B and S (D) and we should perform another experiment, which is exchanging one of



2.22) Cont. terminals with its groupmate. If we still had the

Conduction then the exchanged terminal and its groupmate

are Source and Drain, otherwise the exchanged terminal

is Bulk.

2.23) a) NO, Because in DC model equations of MOSFET, we

always have the product of  $\mu_n C_{ox}$  and  $\frac{W}{L}$ .

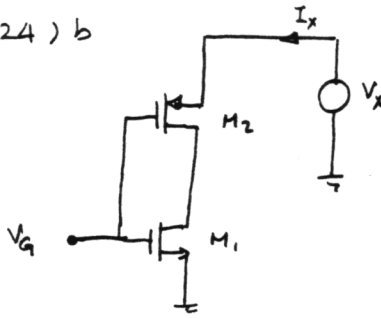
b) NO, Because we cannot obtain as many independent

equations as the unknown quantities. But if the

difference between the aspect ratios is known, then  $\mu_n C_{ox}$

and both  $\frac{W}{L}$ , are attainable.

2.24) b

CASE I :  $V_G < V_{THN} \Rightarrow M_1 : \text{off} \quad I_X = 0$ 

$$g_m = 0$$

CASE II :  $V_G > V_{THN}$ 

for  $0 < V_X < V_G + |V_{THP}| \Rightarrow I_X = 0 \quad (M_2 : \text{off}) \quad g_m = \frac{\partial I_X}{\partial V_G} = 0$

Then  $M_2$  turns on (in sat),  $M_1$  still is in triode region

$$I_X = \frac{1}{2} \mu_p C_{ox} \left( \frac{W}{L} \right)_p (V_X - V_G - |V_{THP}|)^2$$

This is correct until  $M_1$  goes into saturation, when

$$\frac{1}{2} \mu_p C_{ox} \left( \frac{W}{L} \right)_p (V_X - V_G - |V_{THP}|)^2 = \frac{1}{2} \mu_n C_{ox} \left( \frac{W}{L} \right)_n (V_G - V_{THN})^2$$

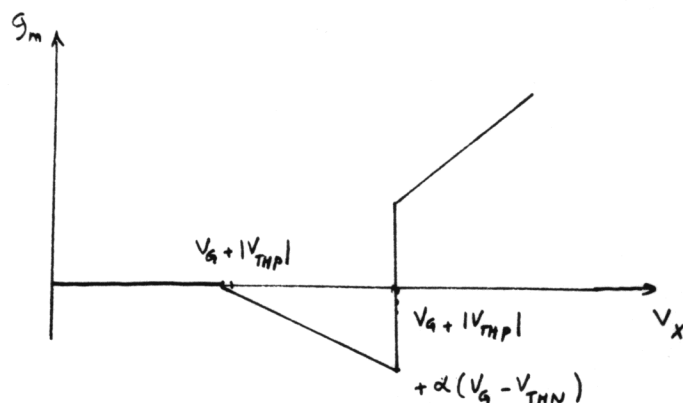
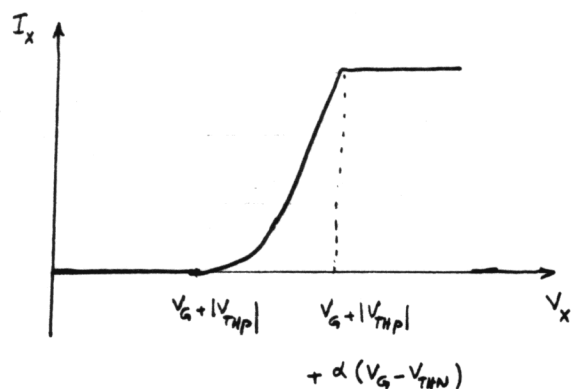
$$\text{i.e.} \quad V_X = V_G + |V_{THP}| + \sqrt{\frac{\mu_n (W/L)_n}{\mu_p (W/L)_p}} (V_G - V_{THN})$$

And afterward,  $M_2$  goes into triode region and  $I_X = \frac{1}{2} \mu_n C_{ox} \left( \frac{W}{L} \right)_n (V_G - V_{THN})^2$

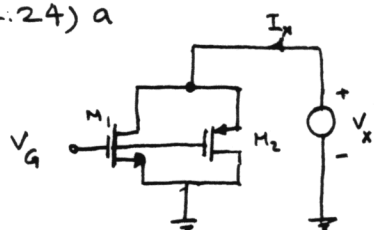
$$\text{So, } 0 < V_X < V_G + |V_{THP}| \Rightarrow I_X = 0 \quad g_m = \frac{\partial I_X}{\partial V_G} = 0$$

$$V_G + |V_{THP}| < V_X < V_G + |V_{THP}| + \alpha (V_G - V_{THN}) \quad I_X = \frac{1}{2} \mu_p C_{ox} \left( \frac{W}{L} \right)_p (V_X - V_G - |V_{THP}|)^2 \quad g_m = \mu_p C_{ox} \left( \frac{W}{L} \right)_p (V_G + |V_{THP}| - V_X)$$

$$V_G + |V_{THP}| + \alpha (V_G - V_{THN}) < V_X \quad I_X = \frac{1}{2} \mu_n C_{ox} \left( \frac{W}{L} \right)_n (V_G - V_{THN})^2 \quad g_m = \mu_n C_{ox} \left( \frac{W}{L} \right)_n (V_G - V_{THN})$$

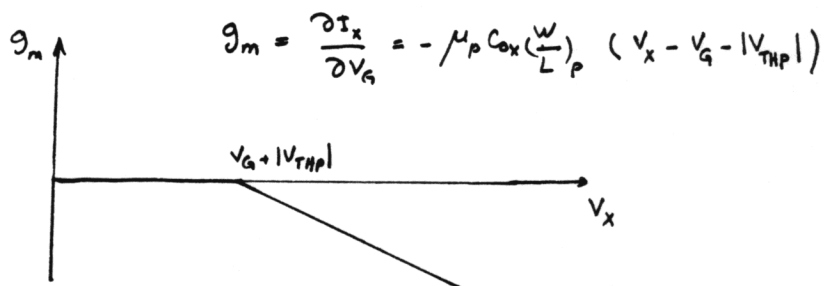
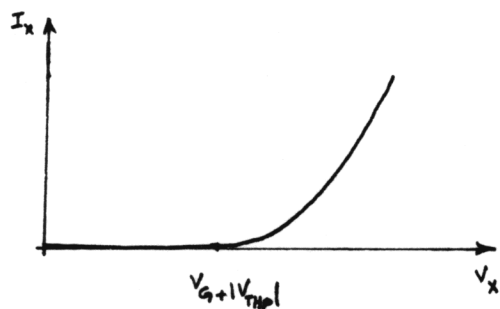


2.24) a

CASE I :  $V_G < V_{THN}$   $M_1$ : off

$$\text{for } 0 < V_x < V_G + |V_{THP}| \quad I_x = 0, \quad g_m = \frac{\partial I_x}{\partial V_G} = 0$$

$$\text{for } V_G + |V_{THP}| < V_x \Rightarrow I_x = \frac{1}{2} \mu_p C_{ox} \left(\frac{W}{L}\right)_p (V_x - V_G - |V_{THP}|)^2$$

CASE II :  $V_G > V_{THN}$ for  $0 < V_x < V_G - V_{THN}$  ( $M_2$ : off  $M_1$ : triode)

$$I_x = \frac{1}{2} \mu_n C_{ox} \left(\frac{W}{L}\right)_n [2(V_G - V_{THN})V_x - V_x^2] \quad g_m = \mu_n C_{ox} \left(\frac{W}{L}\right)_n V_x$$

for  $V_G - V_{THN} < V_x < V_G + |V_{THP}|$  ( $M_2$ : off  $M_1$ : sat)

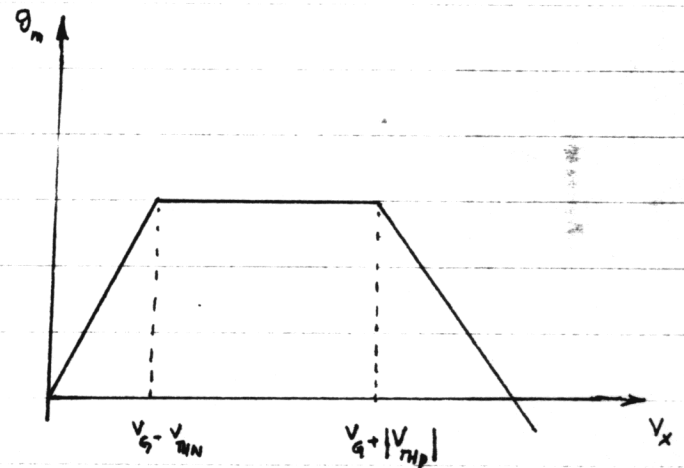
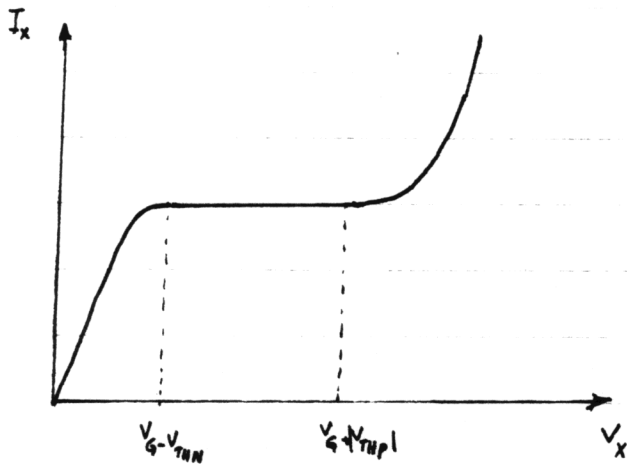
$$I_x = \frac{1}{2} \mu_n C_{ox} \left(\frac{W}{L}\right)_n (V_G - V_{THN})^2 \quad g_m = \mu_n C_{ox} \left(\frac{W}{L}\right)_n (V_G - V_{THN})$$

for  $V_G + |V_{THP}| < V_x$  ( $M_2$ : sat  $M_1$ : sat)

2.24) a Cont.

$$I_x = \frac{1}{2} \mu_n C_{ox} \left(\frac{W}{L}\right)_n (V_G - V_{THN})^2 + \frac{1}{2} \mu_p C_{ox} \left(\frac{W}{L}\right)_p (V_x - V_G - |V_{THP}|)^2$$

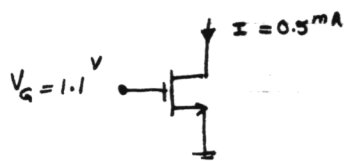
$$g_m = \frac{\partial I_x}{\partial V_G} = \mu_n C_{ox} \left(\frac{W}{L}\right)_n (V_G - V_{THN}) - \mu_p C_{ox} \left(\frac{W}{L}\right)_p (V_x - V_G - |V_{THP}|)$$



2.25)

$$V_{TH} = 0.7$$

$$\lambda = 0.1 \quad (\text{for } L = 0.5 \mu)$$



$$\text{for } L = 0.5 \mu \quad \lambda = 0.1 \rightarrow r_o = \frac{1}{\lambda I_D} = 20 \text{ k}\Omega$$

$$V_{OD} = V_{GS} - V_{TH} = 0.4 \Rightarrow V_{GS} = 1.1 \text{ V}$$

Calculating  $W$ ,

$$I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L_{eff}} (V_{GS} - V_{TH})^2$$

$$0.5 \text{ mA} = \frac{1}{2} \times 0.1343 \frac{\text{mA}}{\text{V}^2} \times \frac{W}{0.5 \mu - 0.16 \mu} \times (0.4)^2$$

$$\frac{W}{L_{eff}} \approx 47$$

 $\Rightarrow$ 

$$W = 15.82 \mu\text{m}$$

$$C_{gs} = \frac{2}{3} WL C_{ox} + WC_{ov} = 25 \text{ fF}$$

$$C_{gd} = WC_{ov} = 4.85 \text{ fF}$$

$$C_{DB} = \frac{W}{2} \epsilon C_j + 2 \left( \frac{W}{2} + E \right) C_{jsw} \quad (@ V_D = 0.4) = 10.7 \text{ fF}$$

(for folded structure)

$$\left( C_j = \frac{C_{j0}}{\left(1 + \frac{V_{DS}}{2\phi_F}\right)^{m_j}} = 0.449 \times 10^{-3} \frac{\text{F}}{\text{m}^2}, \quad C_{jsw} = \frac{C_{jsw0}}{\left(1 + \frac{V_{DS}}{2\phi_F}\right)^{m_{jsw}}} = 0.325 \times 10^{-11} \frac{\text{F}}{\text{m}} \right)$$

$$C_{ox} = 3.84 \times 10^{-3} \frac{\text{F}}{\text{m}}$$

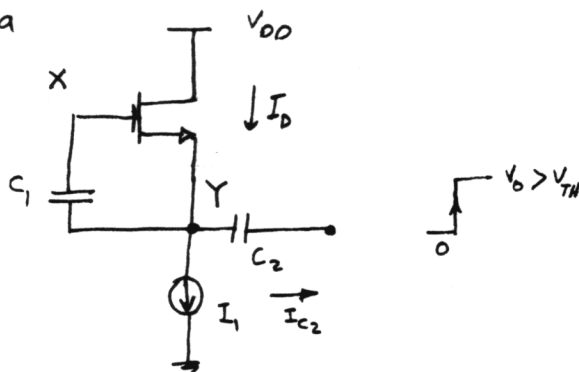
$$C_{j0} = 0.56 \times 10^{-3}$$

$$m_j = 0.6$$

$$C_{jsw0} = 0.35 \times 10^{-11}$$

$$m_{jsw} = 0.2$$

2.26) a



Before applying the pulse

$$X(0^-) = V_{DD}$$

$$Y(0^-) = V_{DD} - V_{TH} - \sqrt{\frac{2I_1}{\mu_n C_{ox} \frac{W}{L}}}$$

After Applying the Pulse

$$X(0^+) = V_{DD} + V_0$$

$$Y(0^+) = V_{DD} - V_{TH} - \sqrt{\frac{2I_1}{\mu_n C_{ox} \frac{W}{L}}} + V_0$$

for  $t > 0$ 

$$\begin{cases} X(t) = V_{DD} + \alpha(t) \\ Y(t) = V_{DD} - V_{TH} - \sqrt{\frac{2I_1}{\mu_n C_{ox} \frac{W}{L}}} + \alpha(t) \end{cases}$$

 $\alpha(0^+) = V_0$ , Device is in triode

$$I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \left[ 2(V_{GS} - V_{TH})V_{DS} - V_{DS}^2 \right] = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \left[ 2 \sqrt{\frac{2I_1}{\mu_n C_{ox} \frac{W}{L}}} - \left( V_{TH} + \sqrt{\frac{2I_1}{\mu_n C_{ox} \frac{W}{L}}} - \alpha(t) \right) \right] \left( V_{TH} + \sqrt{\frac{2I_1}{\mu_n C_{ox} \frac{W}{L}}} - \alpha(t) \right)$$

$$I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \left[ \frac{2I_1}{\mu_n C_{ox} \frac{W}{L}} - (\alpha(t) - V_{TH})^2 \right] = I_1 - \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (\alpha(t) - V_{TH})^2$$

$$I_{C2} = I_D - I_1 = -\frac{1}{2} \mu_n C_{ox} \frac{W}{L} (\alpha(t) - V_{TH})^2 = C_2 \frac{dV_{C2}}{dt} = C_2 \frac{d\alpha(t)}{dt}$$

$$\underbrace{\frac{1}{2} \mu_n C_{ox} \frac{W}{L} \cdot \frac{1}{C_2}}_K dt = \frac{-d\alpha}{(\alpha - V_{TH})^2} \Rightarrow Kt = \frac{1}{\alpha - V_{TH}} - \frac{1}{V_0 - V_{TH}}$$

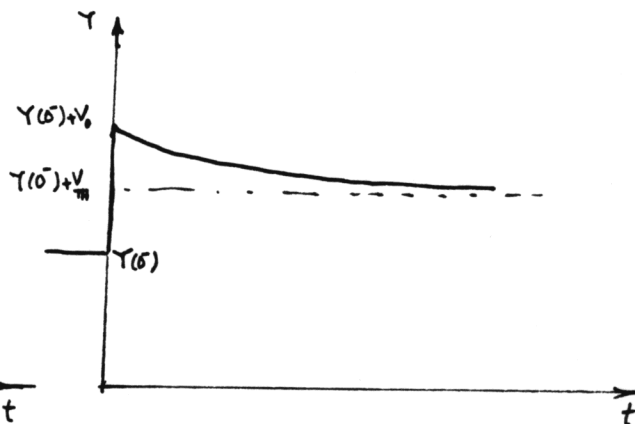
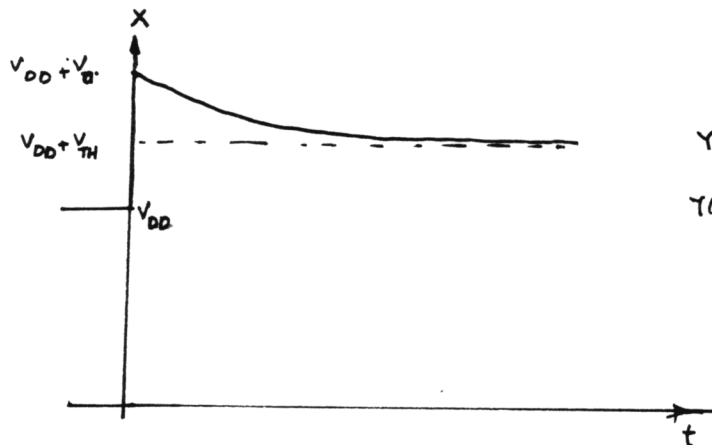
$$\Rightarrow \alpha(t) = V_{TH} + \frac{1}{Kt + \frac{1}{V_0 - V_{TH}}}$$

$$\alpha(\infty) = V_{TH}$$

2.26) a Cont.

$$X(\infty) = V_{DD} + V_{TH}$$

$$Y(\infty) = V_{DD} - V_{TH} - \sqrt{\frac{2I_1}{\mu_n C_{ox} \frac{W}{L}}} + V_{TH} = V_{DD} - \sqrt{\frac{2I_1}{\mu_n C_{ox} \frac{W}{L}}}$$



2.26) b

Before applying the pulse.

$$X(0^-) = V_{DD}$$

$$Y(0^-) = V_{DD} - V_{TH} - \sqrt{\frac{2I_1}{\mu_n C_{ox} \frac{W}{L}}}$$

After applying the pulse

$$X(0^+) = V_{DD} - V_{TH}$$

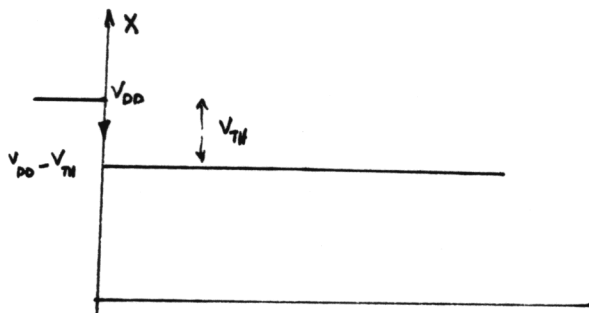
$$Y(0^+) = V_{DD} - V_{TH} - \sqrt{\frac{2I_1}{\mu_n C_{ox} \frac{W}{L}}} - V_{TH}$$

After applying the pulse, device remains in the saturation

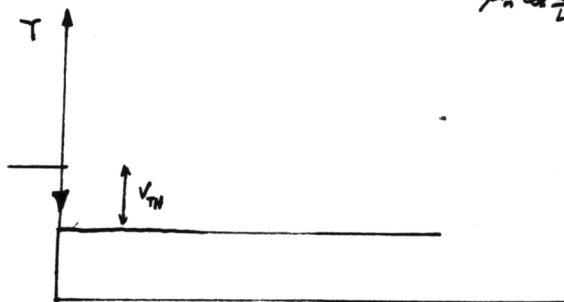
region, and its current doesn't change, so,  $I_{C1} = I_{C2} = 0$ 

Therefore, the circuit keeps its state.

$$X(t) = X(0^+) = V_{DD} - V_{TH}$$



$$Y(t) = Y(0^+) = V_{DD} - 2V_{TH} - \sqrt{\frac{2I_1}{\mu_n C_{ox} \frac{W}{L}}}$$



2.27)

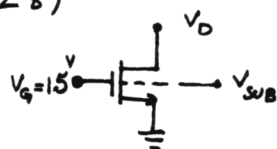
$$I_D = I_0 \exp \frac{V_{GS}}{\xi V_T}$$

$$\frac{I_{D2}}{I_{D1}} = \exp \frac{V_{GS2} - V_{GS1}}{\xi V_T} \quad \frac{I_{D2}}{I_{D1}} = 10 \quad \Rightarrow \quad \Delta V_{GS} = \xi V_T \ln 10$$

$$\Delta V_{GS} = 1.5 \times \ln 10 \times 26 \text{ mV} = 89.8 \text{ mV}$$

$$g_m = \frac{I_D}{\xi V_T} = \frac{10 \mu\text{A}}{1.5 \times 26 \text{ mV}} = 0.26 \text{ mA/V}$$

2.28)



- a) If we decrease  $V_D$  below zero, Source and drain exchange their roles and device operates in the triode region.

- b) If we increase  $V_B$ ,  $V_{TH}$  decreases, because

$$\Delta V_{TH} = \gamma (\sqrt{2\phi_F - V_B} - \sqrt{2\phi_F}) \text{ is negative.}$$

Therefore,  $I_D$  increases.